

## 300-MHz to 4-GHz Quadrature Modulator

 Check for Samples: [TRF3705](#)

### FEATURES

- **High Linearity:**
  - Output IP3: 30 dBm at 1850 MHz
- **Low Output Noise Floor: –160 dBm/Hz**
- **78-dBc Single-Carrier WCDMA ACPR at –10-dBm Channel Power**
- **Unadjusted Carrier Suppression: –40 dBm**
- **Unadjusted Sideband Suppression: –45 dBc**
- **Single Supply: 3.3-V Operation**
- **1-bit Gain Step Control**
- **Fast Power-Up/Power-Down**

### APPLICATIONS

- **Cellular Base Station Transmitter**
- **CDMA: IS95, UMTS, CDMA2000, TD-SCDMA**
- **LTE (Long Term Evolution)**
- **TDMA: GSM, EDGE/UWC-136**
- **Multicarrier GSM (MC-GSM)**
- **Wireless MAN Wideband Transceivers**

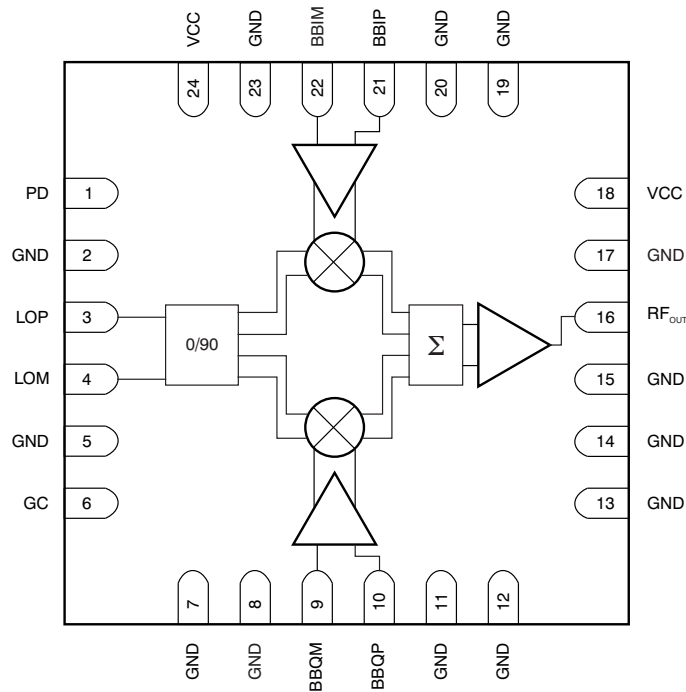
### DESCRIPTION

The TRF3705 is a low-noise direct quadrature modulator, capable of converting complex modulated signals from baseband or IF directly up to RF. The TRF3705 is a high-performance, superior-linearity device that is ideal to up-convert to RF frequencies of 300 MHz<sup>(1)</sup> through 4 GHz. The modulator is implemented as a double-balanced mixer.

The RF output block consists of a differential-to-single-ended converter that is capable of driving a single-ended 50-Ω load. The TRF3705 requires a 0.25-V common-mode voltage for optimum linearity performance. The TRF3705 also provides a fast power-down pin that can be used to reduce power dissipation in TDD applications.

The TRF3705 is available in an RGE-24 VQFN package.

(1) Appropriate matching network is required for optimal performance at 300 MHz.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### AVAILABLE DEVICE OPTIONS<sup>(1)</sup>

| PRODUCT | PACKAGE-LEAD | PACKAGE DESIGNATOR | SPECIFIED TEMPERATURE RANGE | PACKAGE MARKING | ORDERING NUMBER | TRANSPORT MEDIA, QUANTITY |
|---------|--------------|--------------------|-----------------------------|-----------------|-----------------|---------------------------|
| TRF3705 | RGE-24       | RGE                | –40°C to +85°C              | TRF3705IRGE     | TRF3705IRGET    | Tape and Reel, 250        |
|         |              |                    |                             |                 | TRF3705IRGER    | Tape and Reel, 3000       |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the device product folder at [www.ti.com](http://www.ti.com).

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Over operating free-air temperature range (unless otherwise noted).

|   | VALUE                     | UNIT |   |
|---|---------------------------|------|---|
| Supply voltage range <sup>(2)</sup>                 | –0.3 to +6                | V    |   |
| Digital I/O voltage range                           | –0.3 to $V_{CC} + 0.5$    | V    |   |
| Operating virtual junction temperature range, $T_J$ | –40 to +150               | °C   |   |
| Operating ambient temperature range, $T_A$          | –40 to +85                | °C   |   |
| Storage temperature range, $T_{stg}$                | –65 to +150               | °C   |   |
| ESD ratings   | Human body model, HBM     | 4000 | V |
|   | Charged device model, CDM | 250  | V |
|   | Machine model, MM         | 200  | V |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

### RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted).

|                               | MIN  | NOM | MAX | UNIT |
|-------------------------------|------|-----|-----|------|
| $V_{CC}$ Power-supply voltage | 3.15 | 3.3 | 3.6 | V    |

### THERMAL CHARACTERISTICS

Over recommended operating free-air temperature range (unless otherwise noted).

| PARAMETER <sup>(1)</sup>                                | TEST CONDITIONS         | MIN | TYP  | MAX | UNIT |
|---|-------------------------|-----|------|-----|------|
| $R_{\theta JA}$ Thermal resistance, junction-to-ambient | High-K board, still air |     | 29.4 |     | °C/W |
| $R_{\theta JC}$ Thermal resistance, junction-to-board   |                         |     | 18.6 |     | °C/W |

(1) Determined using JEDEC standard JESD-51 with high-K board

**THERMAL INFORMATION**

| THERMAL METRIC <sup>(1)</sup> |  | TRF3705    | UNITS |
|-------------------------------|--|------------|-------|
|                               |  | RGE (VQFN) |       |
|                               |  | 24 PINS    |       |
| $\theta_{JA}$                 | Junction-to-ambient thermal resistance       | 38.4       | °C/W  |
| $\theta_{JcTop}$              | Junction-to-case (top) thermal resistance    | 42.5       |       |
| $\theta_{JB}$                 | Junction-to-board thermal resistance         | 16.6       |       |
| $\psi_{JT}$                   | Junction-to-top characterization parameter   | 0.9        |       |
| $\psi_{JB}$                   | Junction-to-board characterization parameter | 16.6       |       |
| $\theta_{JcBot}$              | Junction-to-case (bottom) thermal resistance | 6.6        |       |

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

**ELECTRICAL CHARACTERISTICS: GENERAL**

Over recommended operating conditions; at power supply = 3.3 V and  $T_A = +25^\circ\text{C}$ , unless otherwise noted.

| PARAMETERS               |                                      | TEST CONDITIONS                                    | MIN | TYP  | MAX | UNIT          |
|--------------------------|--------------------------------------|--|-----|------|-----|---------------|
| <b>DC PARAMETERS</b>     |                                      |  |     |      |     |               |
| $I_{CC}$                 | Total supply current                 | $T_A = +25^\circ\text{C}$ , device on (PD = low)   |     | 306  |     | mA            |
|                          |                                      | $T_A = +25^\circ\text{C}$ , device off (PD = high) |     | 35   |     | $\mu\text{A}$ |
| <b>LO INPUT</b>          |                                      |  |     |      |     |               |
| $f_{LO}$                 | LO low frequency                     |  |     | 300  |     | MHz           |
|                          | LO high frequency                    |  |     | 4000 |     | MHz           |
|                          | LO input power                       |  | -10 | 0    | +15 | dBm           |
| <b>BASEBAND INPUTS</b>   |                                      |  |     |      |     |               |
| $V_{CM}$                 | I and Q input dc common-mode voltage |  |     | 0.25 | 0.5 | V             |
| BW                       | 1-dB input frequency bandwidth       |  |     | 1000 |     | MHz           |
| $Z_i$                    | Input impedance                      | Resistance   |     | 8    |     | k $\Omega$    |
|                          |                                      | Parallel capacitance                               |     | 4.6  |     | pF            |
| <b>POWER ON/OFF</b>      |                                      |  |     |      |     |               |
|                          | Turn on time                         | PD = low to 90% final output power                 |     | 0.2  |     | $\mu\text{s}$ |
|                          | Turn off time                        | PD = high to initial output power -30 dB           |     | 0.2  |     | $\mu\text{s}$ |
| <b>DIGITAL INTERFACE</b> |                                      |  |     |      |     |               |
| $V_{IH}$                 | PD high-level input voltage          |  | 2   |      |     | V             |
| $V_{IL}$                 | PD low-level input voltage           |  |     |      | 0.8 | V             |

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions; at power supply = 3.3 V,  $T_A = +25^\circ\text{C}$ ,  $V_{CM} = 0.25\text{ V}$ ; LO Power = 0 dBm, single-ended (LOP); GC set low,  $V_{IN\ BB} = 1.0\text{ V}_{PP}$  (diff) in quadrature, and  $f_{BB} = 5.5\text{ MHz}$ , standard broadband output matching circuit, unless otherwise noted.

| PARAMETERS                                  |                                 | TEST CONDITIONS   | MIN | TYP    | MAX | UNIT   |
|---|---------------------------------|---|-----|--------|-----|--------|
| <b><math>f_{LO} = 400\text{ MHz}</math></b> |                                 |   |     |        |     |        |
| G   | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                |     | -4.7   |     | dB     |
|   |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                               |     | -1.9   |     | dB     |
| P <sub>OUT</sub>                            | Output power                    | GC set low  |     | -0.7   |     | dBm    |
|   |                                 | GC set high   |     | 2.1    |     | dBm    |
| P1dB  | Output compression point        | GC set low  |     | 8.5    |     | dBm    |
|   |                                 | GC set high   |     | 9.1    |     | dBm    |
| IP3   | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                          |     | 26.0   |     | dBm    |
|   |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                         |     | 25.4   |     | dBm    |
| IP2   | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low                                     |     | 60.2   |     | dBm    |
|   |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high                                    |     | 61.9   |     | dBm    |
| SBS   | Unadjusted sideband suppression |   |     | -57.4  |     | dBc    |
| CF  | Unadjusted carrier feedthrough  | Measured at LO frequency  |     | -51.6  |     | dBm    |
|   |                                 | Measured at 2 • LO  |     | -50    |     | dBm    |
|   |                                 | Measured at 3 • LO  |     | -49    |     | dBm    |
|   | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO   |     | -166.7 |     | dBm/Hz |
| HD2 <sub>BB</sub>                           | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -67    |     | dBc    |
| HD3 <sub>BB</sub>                           | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -64    |     | dBc    |
| <b><math>f_{LO} = 750\text{ MHz}</math></b> |                                 |   |     |        |     |        |
| G   | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                |     | 0.2    |     | dB     |
|   |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                               |     | 3.0    |     | dB     |
| P <sub>OUT</sub>                            | Output power                    | GC set low  |     | 4.2    |     | dBm    |
|   |                                 | GC set high   |     | 7.0    |     | dBm    |
| P1dB  | Output compression point        | GC set low  |     | 13.3   |     | dBm    |
|   |                                 | GC set high   |     | 13.9   |     | dBm    |
| IP3   | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                          |     | 31.5   |     | dBm    |
|   |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                         |     | 30.8   |     | dBm    |
| IP2   | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low                                     |     | 73.6   |     | dBm    |
|   |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high                                    |     | 80.5   |     | dBm    |
| SBS   | Unadjusted sideband suppression |   |     | -45.2  |     | dBc    |
| CF  | Unadjusted carrier feedthrough  | Measured at LO frequency  |     | -45.7  |     | dBm    |
|   |                                 | Measured at 2 • LO  |     | -46    |     | dBm    |
|   |                                 | Measured at 3 • LO  |     | -53.5  |     | dBm    |
|   | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO   |     | -159.9 |     | dBm/Hz |
| HD2 <sub>BB</sub>                           | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -70    |     | dBc    |
| HD3 <sub>BB</sub>                           | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -66    |     | dBc    |

**ELECTRICAL CHARACTERISTICS (continued)**

Over recommended operating conditions; at power supply = 3.3 V,  $T_A = +25^\circ\text{C}$ ,  $V_{CM} = 0.25\text{ V}$ ; LO Power = 0 dBm, single-ended (LOP); GC set low,  $V_{IN\ BB} = 1.0\text{ V}_{PP}$  (diff) in quadrature, and  $f_{BB} = 5.5\text{ MHz}$ , standard broadband output matching circuit, unless otherwise noted.

| PARAMETERS                                   |                                 | TEST CONDITIONS   | MIN | TYP    | MAX | UNIT   |
|--|---------------------------------|---|-----|--------|-----|--------|
| <b><math>f_{LO} = 900\text{ MHz}</math></b>  |                                 |   |     |        |     |        |
| G  | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                |     | 0.3    |     | dB     |
|  |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                               |     | 3.1    |     | dB     |
| P <sub>OUT</sub>                             | Output power                    | GC set low  |     | 4.3    |     | dBm    |
|  |                                 | GC set high   |     | 7.1    |     | dBm    |
| P1dB   | Output compression point        | GC set low  |     | 13.2   |     | dBm    |
|  |                                 | GC set high   |     | 13.7   |     | dBm    |
| IP3  | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                          |     | 31.7   |     | dBm    |
|  |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                         |     | 30.9   |     | dBm    |
| IP2  | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low                                     |     | 71.5   |     | dBm    |
|  |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high                                    |     | 75.3   |     | dBm    |
| SBS  | Unadjusted sideband suppression |   |     | -43.8  |     | dBc    |
| CF   | Unadjusted carrier feedthrough  | Measured at LO frequency  |     | -48.5  |     | dBm    |
|  |                                 | Measured at 2 • LO  |     | -53    |     | dBm    |
|  |                                 | Measured at 3 • LO  |     | -50    |     | dBm    |
|  | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO   |     | -157.9 |     | dBm/Hz |
| HD2 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -80    |     | dBc    |
| HD3 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -65    |     | dBc    |
| <b><math>f_{LO} = 1840\text{ MHz}</math></b> |                                 |   |     |        |     |        |
| G  | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                |     | -0.1   |     | dB     |
|  |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                               |     | 2.5    |     | dB     |
| P <sub>OUT</sub>                             | Output power                    | GC set low  |     | 3.9    |     | dBm    |
|  |                                 | GC set high   |     | 6.5    |     | dBm    |
| P1dB   | Output compression point        | GC set low  |     | 13.2   |     | dBm    |
|  |                                 | GC set high   |     | 13.6   |     | dBm    |
| IP3  | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                          |     | 32.1   |     | dBm    |
|  |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                         |     | 30.3   |     | dBm    |
| IP2  | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low                                     |     | 60.8   |     | dBm    |
|  |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high                                    |     | 62.0   |     | dBm    |
| SBS  | Unadjusted sideband suppression |   |     | -43.4  |     | dBc    |
| CF   | Unadjusted carrier feedthrough  | Measured at LO frequency  |     | -42.4  |     | dBm    |
|  |                                 | Measured at 2 • LO  |     | -41    |     | dBm    |
|  |                                 | Measured at 3 • LO  |     | -53    |     | dBm    |
|  | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO   |     | -158.8 |     | dBm/Hz |
| HD2 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -69    |     | dBc    |
| HD3 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -80    |     | dBc    |

## ELECTRICAL CHARACTERISTICS (continued)

Over recommended operating conditions; at power supply = 3.3 V,  $T_A = +25^\circ\text{C}$ ,  $V_{CM} = 0.25\text{ V}$ ; LO Power = 0 dBm, single-ended (LOP); GC set low,  $V_{IN\ BB} = 1.0\text{ V}_{PP}$  (diff) in quadrature, and  $f_{BB} = 5.5\text{ MHz}$ , standard broadband output matching circuit, unless otherwise noted.

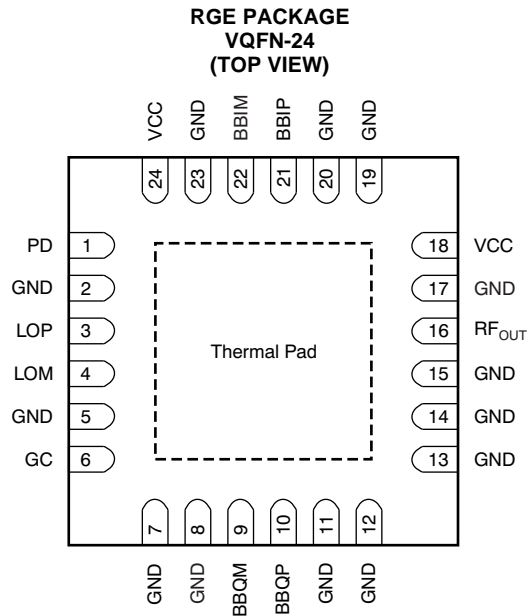
| PARAMETERS                                   |                                 | TEST CONDITIONS   | MIN | TYP    | MAX | UNIT   |
|--|---------------------------------|---|-----|--------|-----|--------|
| <b><math>f_{LO} = 2140\text{ MHz}</math></b> |                                 |   |     |        |     |        |
| G  | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                |     | 0.1    |     | dB     |
|  |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                               |     | 2.9    |     | dB     |
| P <sub>OUT</sub>                             | Output power                    | GC set low  |     | 4.1    |     | dBm    |
|  |                                 | GC set high   |     | 6.9    |     | dBm    |
| P1dB   | Output compression point        | GC set low  |     | 13.1   |     | dBm    |
|  |                                 | GC set high   |     | 13.5   |     | dBm    |
| IP3  | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                          |     | 28.6   |     | dBm    |
|  |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                         |     | 27.6   |     | dBm    |
| IP2  | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low                                     |     | 65.5   |     | dBm    |
|  |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high                                    |     | 68.2   |     | dBm    |
| SBS  | Unadjusted sideband suppression |   |     | -45.6  |     | dBc    |
| CF   | Unadjusted carrier feedthrough  | Measured at LO frequency  |     | -39.3  |     | dBm    |
|  |                                 | Measured at 2 • LO  |     | -37    |     | dBm    |
|  |                                 | Measured at 3 • LO  |     | -46    |     | dBm    |
|  | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO   |     | -160.0 |     | dBm/Hz |
| HD2 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -61    |     | dBc    |
| HD3 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -60    |     | dBc    |
| <b><math>f_{LO} = 2600\text{ MHz}</math></b> |                                 |   |     |        |     |        |
| G  | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                |     | -0.8   |     | dB     |
|  |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                               |     | 2.0    |     | dB     |
| P <sub>OUT</sub>                             | Output power                    | GC set low  |     | 3.2    |     | dBm    |
|  |                                 | GC set high   |     | 5.6    |     | dBm    |
| P1dB   | Output compression point        | GC set low  |     | 12.5   |     | dBm    |
|  |                                 | GC set high   |     | 12.8   |     | dBm    |
| IP3  | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                          |     | 28.0   |     | dBm    |
|  |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                         |     | 27.2   |     | dBm    |
| IP2  | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low                                     |     | 67.9   |     | dBm    |
|  |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high                                    |     | 66.4   |     | dBm    |
| SBS  | Unadjusted sideband suppression |   |     | -52.9  |     | dBm    |
| CF   | Unadjusted carrier feedthrough  | Measured at LO frequency  |     | -37.8  |     | dBm    |
|  |                                 | Measured at 2 • LO  |     | -41    |     | dBm    |
|  |                                 | Measured at 3 • LO  |     | -42    |     | dBm    |
|  | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO   |     | -160.6 |     | dBm/Hz |
| HD2 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -67    |     | dBc    |
| HD3 <sub>BB</sub>                            | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 $V_{PP}$ each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -59    |     | dBc    |

**ELECTRICAL CHARACTERISTICS (continued)**

Over recommended operating conditions; at power supply = 3.3 V,  $T_A = +25^\circ\text{C}$ ,  $V_{CM} = 0.25\text{ V}$ ; LO Power = 0 dBm, single-ended (LOP); GC set low,  $V_{IN\ BB} = 1.0\text{ V}_{PP}$  (diff) in quadrature, and  $f_{BB} = 5.5\text{ MHz}$ , standard broadband output matching circuit, unless otherwise noted.

| PARAMETERS                 |                                 | TEST CONDITIONS  | MIN | TYP    | MAX | UNIT   |
|----------------------------|---------------------------------|--|-----|--------|-----|--------|
| $f_{LO} = 3500\text{ MHz}$ |                                 |  |     |        |     |        |
| G                          | Voltage gain                    | Output RMS voltage over input I (or Q) RMS voltage, GC set low                                       |     | -1.0   |     | dB     |
|                            |                                 | Output RMS voltage over input I (or Q) RMS voltage, GC set high                                      |     | 1.8    |     | dB     |
| P <sub>OUT</sub>           | Output power                    | GC set low   |     | 3.0    |     | dBm    |
|                            |                                 | GC set high  |     | 5.8    |     | dBm    |
| P1dB                       | Output compression point        | GC set low   |     | 12.1   |     | dBm    |
|                            |                                 | GC set high  |     | 12.3   |     | dBm    |
| IP3                        | Output IP3                      | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set low                                 |     | 23.8   |     | dBm    |
|                            |                                 | $f_{BB1} = 4.5\text{ MHz}$ ; $f_{BB2} = 5.5\text{ MHz}$ ; GC set high                                |     | 25.3   |     | dBm    |
| IP2                        | Output IP2                      | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set low  |     | 47.8   |     | dBm    |
|                            |                                 | Measured at $f_{LO} + (f_{BB1} \pm f_{BB2})$ , GC set high   |     | 48.6   |     | dBm    |
| SBS                        | Unadjusted sideband suppression |  |     | -45.2  |     | dBm    |
| CF                         | Unadjusted carrier feedthrough  | Measured at LO frequency   |     | -31.6  |     | dBm    |
|                            |                                 | Measured at 2 • LO   |     | -30    |     | dBm    |
|                            |                                 | Measured at 3 • LO   |     | -53    |     | dBm    |
|                            | Output noise floor              | DC only to BB inputs; 10-MHz offset from LO  |     | -160.6 |     | dBm/Hz |
| HD2 <sub>BB</sub>          | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 V <sub>PP</sub> each at $f_{LO} \pm (2 \bullet f_{BB})$ |     | -54    |     | dBc    |
| HD3 <sub>BB</sub>          | Baseband harmonics              | Measured with $\pm 1\text{-MHz}$ tone at 0.5 V <sub>PP</sub> each at $f_{LO} \pm (3 \bullet f_{BB})$ |     | -50    |     | dBc    |

## DEVICE INFORMATION



## PIN FUNCTIONS

| PIN |                   | I/O | DESCRIPTION                                   |
|-----|-------------------|-----|---|
| NO. | NAME              |     |   |
| 1   | PD                | I   | Power-down digital input (high = device off)  |
| 2   | GND               | I   | Ground  |
| 3   | LOP               | I   | Local oscillator input                        |
| 4   | LOM               | I   | Local oscillator input                        |
| 5   | GND               | I   | Ground  |
| 6   | GC                | I   | Gain control digital input (high = high gain) |
| 7   | GND               | —   | Ground or leave unconnected                   |
| 8   | GND               | I   | Ground  |
| 9   | BBQM              | I   | In-quadrature input                           |
| 10  | BBQP              | I   | In-quadrature input                           |
| 11  | GND               | I   | Ground  |
| 12  | GND               | I   | Ground  |
| 13  | GND               | I   | Ground  |
| 14  | GND               | I   | Ground  |
| 15  | GND               | I   | Ground  |
| 16  | RF <sub>OUT</sub> | O   | RF output                                     |
| 17  | GND               | I   | Ground  |
| 18  | VCC               | I   | Power supply                                  |
| 19  | GND               | I   | Ground  |
| 20  | GND               | I   | Ground  |
| 21  | BBIP              | I   | In-phase input                                |
| 22  | BBIM              | I   | In-phase input                                |
| 23  | GND               | I   | Ground  |
| 24  | VCC               | I   | Power supply                                  |



**TYPICAL CHARACTERISTICS: Single-Tone Baseband**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 5.5 MHz; baseband I/Q amplitude =  $1 \cdot V_{pp}$  differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

**OUTPUT POWER vs LO FREQUENCY ( $f_{LO}$ ) AND TEMPERATURE**

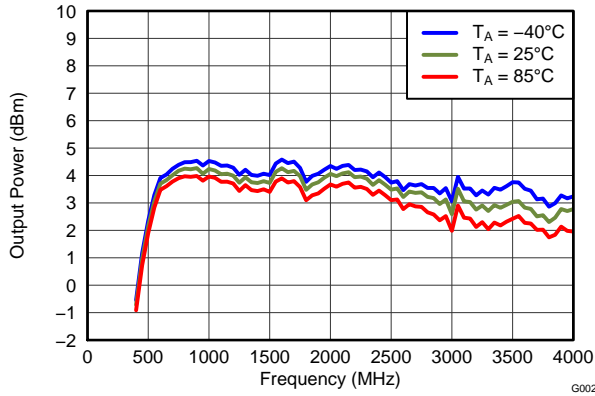


Figure 1.

**OUTPUT POWER vs LO FREQUENCY ( $f_{LO}$ ) AND SUPPLY VOLTAGE**

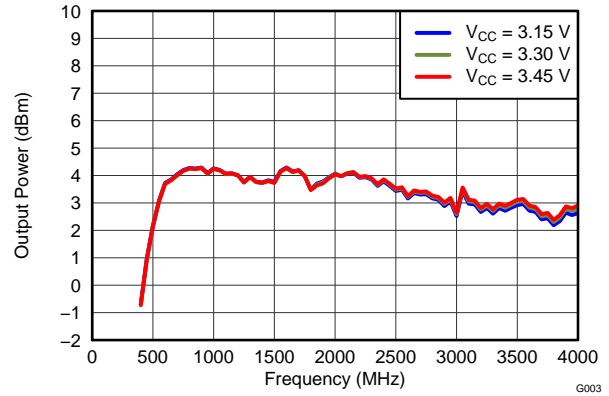


Figure 2.

**OUTPUT POWER vs LO FREQUENCY ( $f_{LO}$ ) OVER LO DRIVE LEVEL**

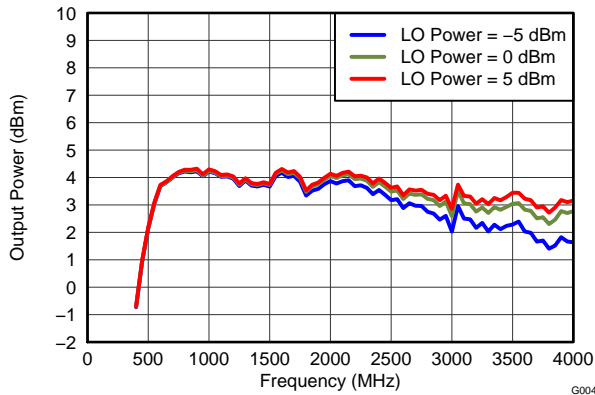


Figure 3.

**OUTPUT POWER vs LO FREQUENCY ( $f_{LO}$ ) AND GAIN SELECT SETTING**

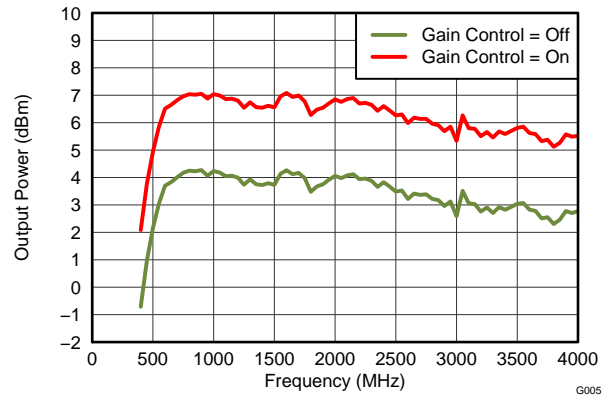


Figure 4.

**OUTPUT POWER vs LO FREQUENCY ( $f_{LO}$ ) AND TEMPERATURE AT  $V_{CM} = 0.5\text{ V}$**

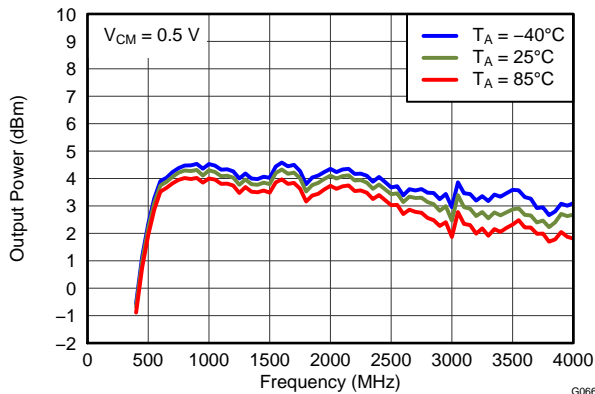


Figure 5.

**OUTPUT POWER vs BASEBAND VOLTAGE AT 2140 MHz**

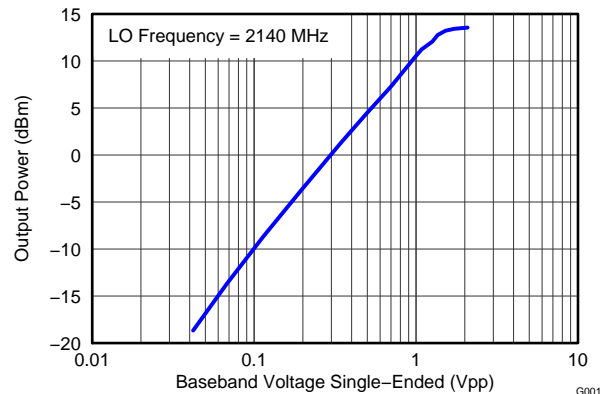


Figure 6.

**TYPICAL CHARACTERISTICS: Single-Tone Baseband (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 5.5 MHz; baseband I/Q amplitude =  $1 \cdot V_{PP}$  differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

**P1dB vs LO FREQUENCY ( $f_{LO}$ ) AND TEMPERATURE**

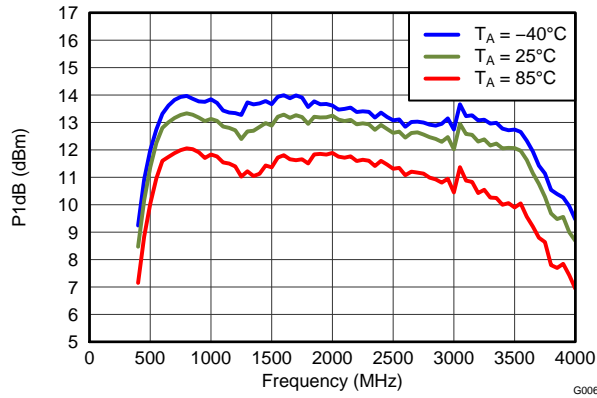


Figure 7.

**P1dB vs LO FREQUENCY ( $f_{LO}$ ) AND SUPPLY VOLTAGE**

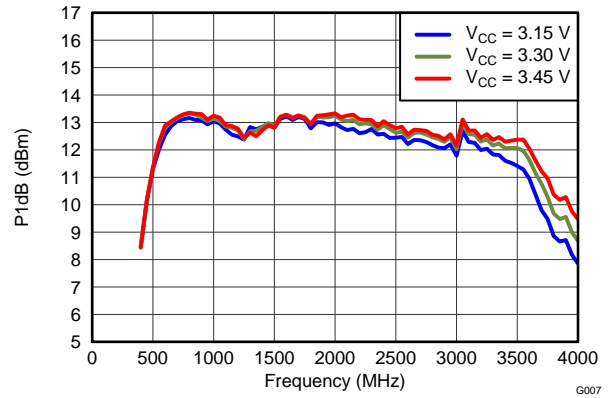


Figure 8.

**P1dB vs LO FREQUENCY ( $f_{LO}$ ) AND LO DRIVE LEVEL**

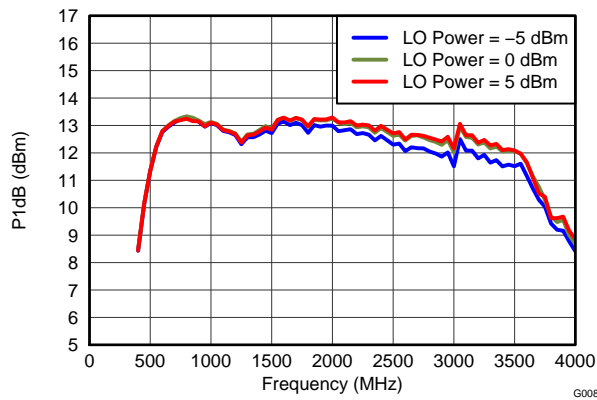


Figure 9.

**P1dB vs LO FREQUENCY ( $f_{LO}$ ) AND GAIN SELECT SETTING**

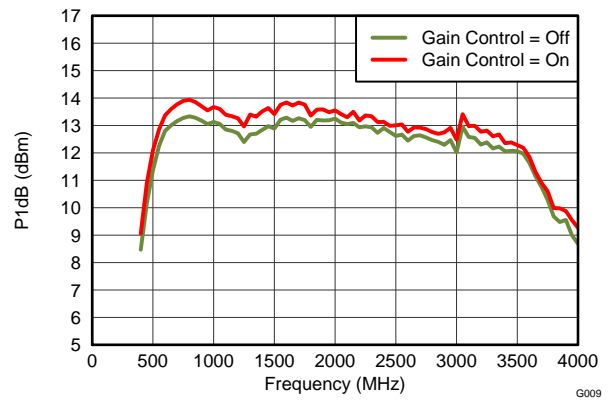


Figure 10.

**P1dB vs LO FREQUENCY ( $f_{LO}$ ) AND TEMPERATURE AT  $V_{CM} = 0.5\text{ V}$**

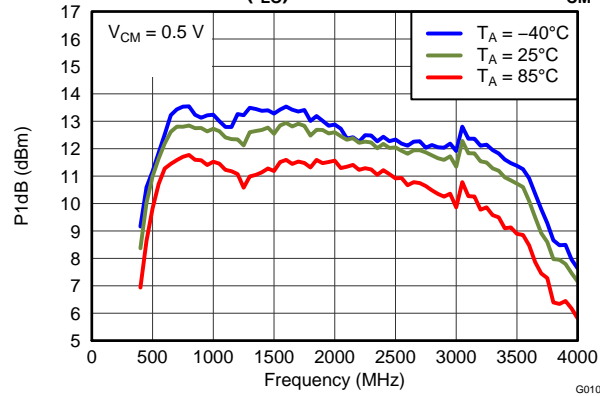


Figure 11.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

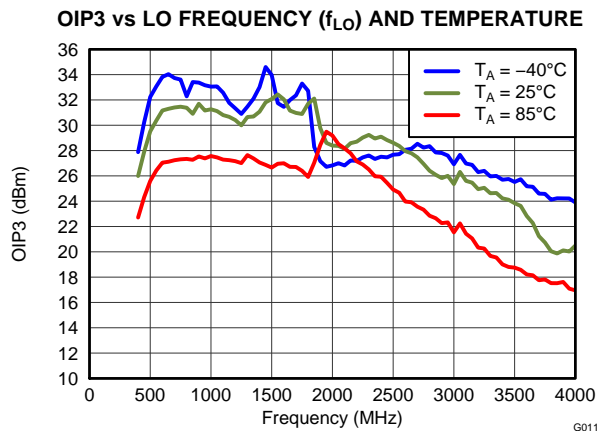


Figure 12.

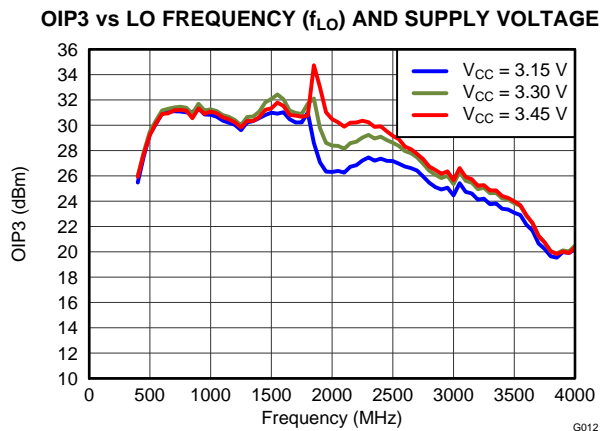


Figure 13.

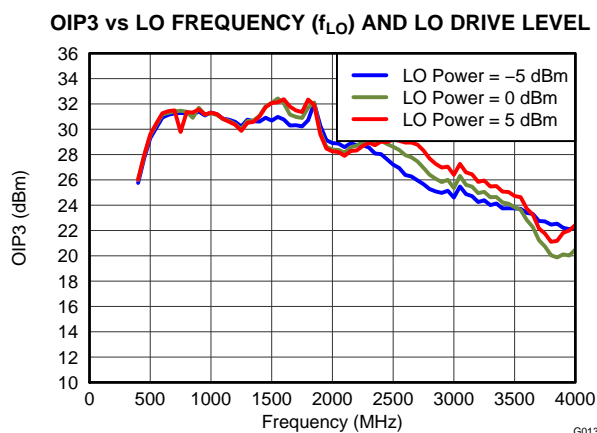


Figure 14.

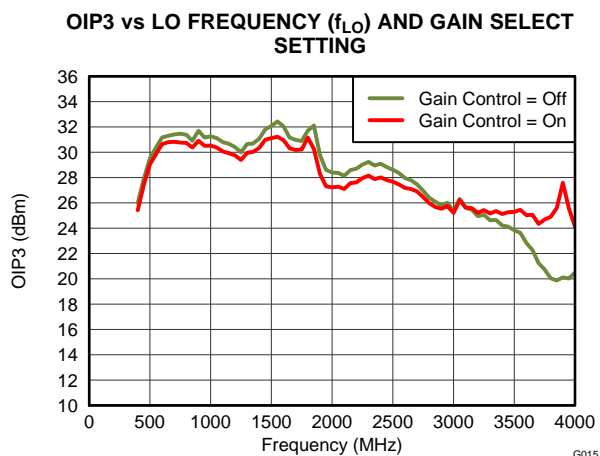


Figure 15.

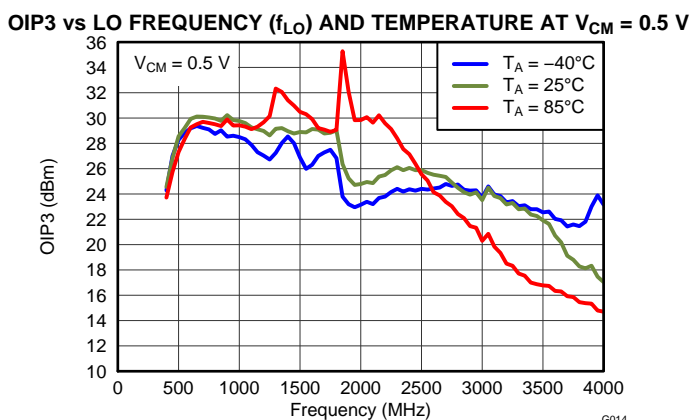


Figure 16.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

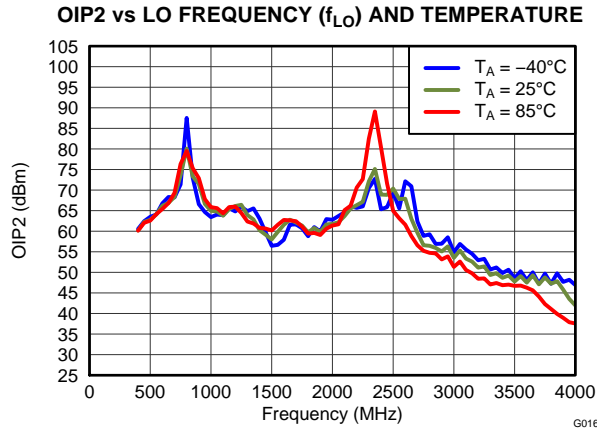


Figure 17.

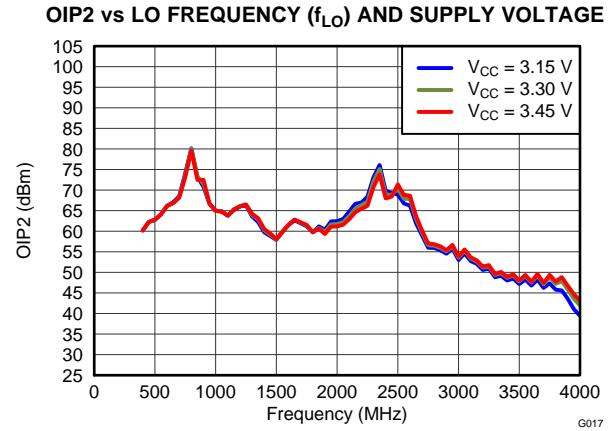


Figure 18.

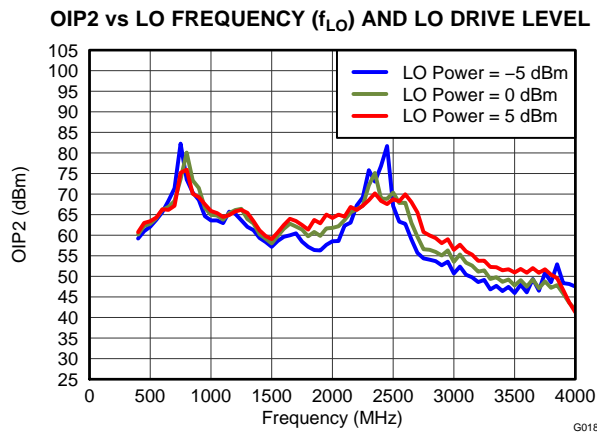


Figure 19.

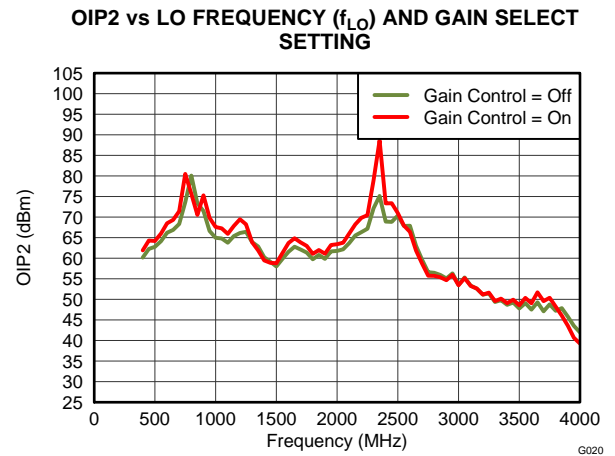


Figure 20.

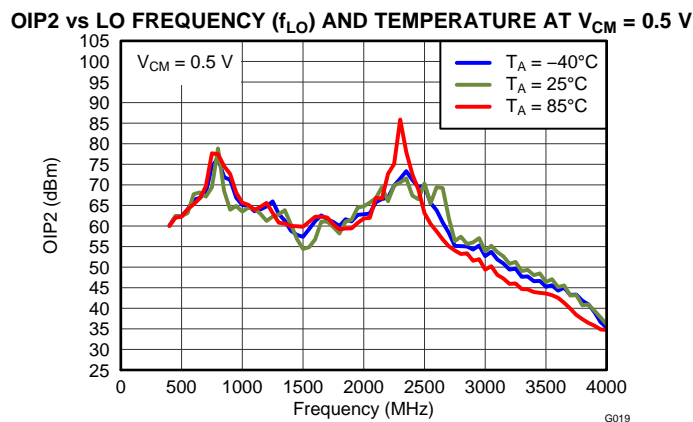


Figure 21.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

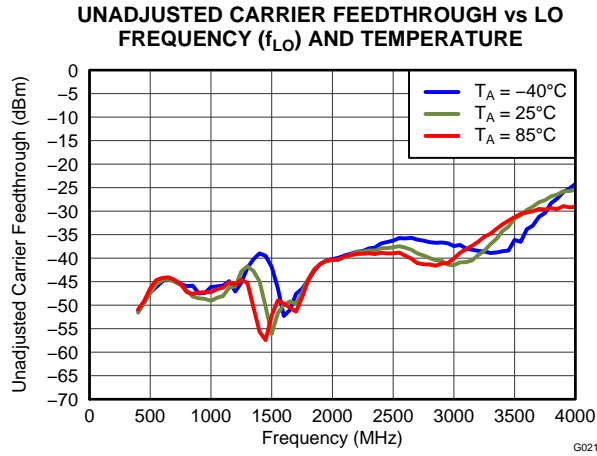


Figure 22.

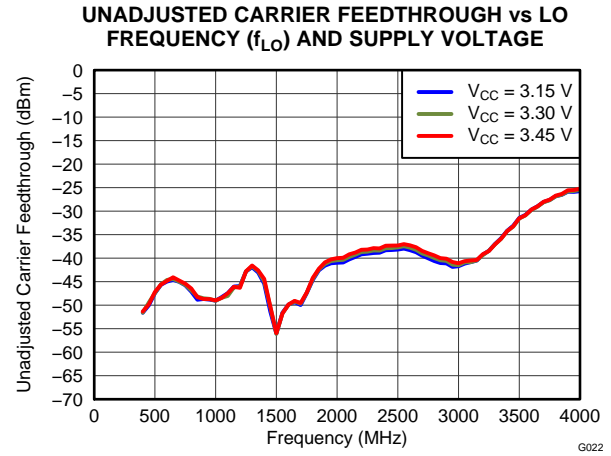


Figure 23.

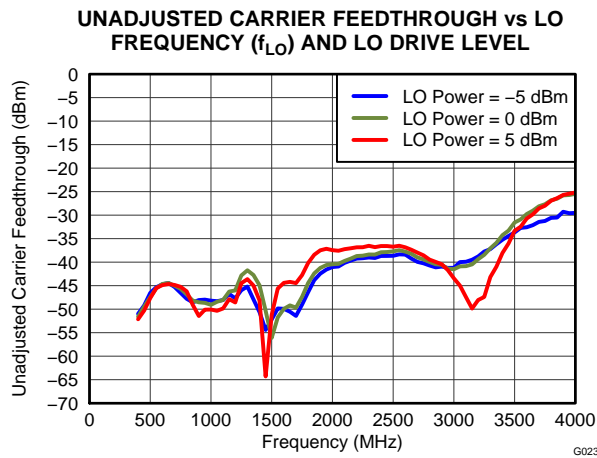


Figure 24.

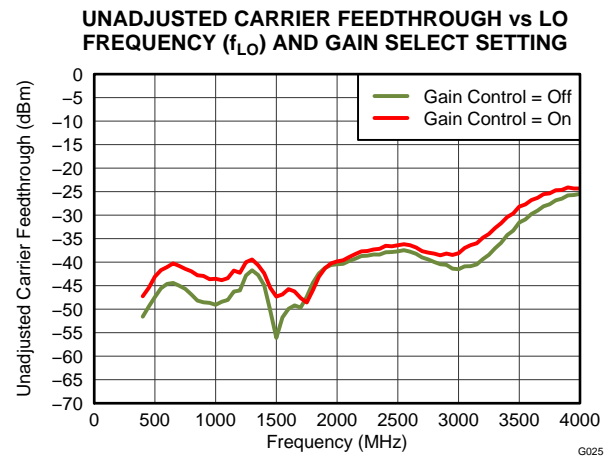


Figure 25.

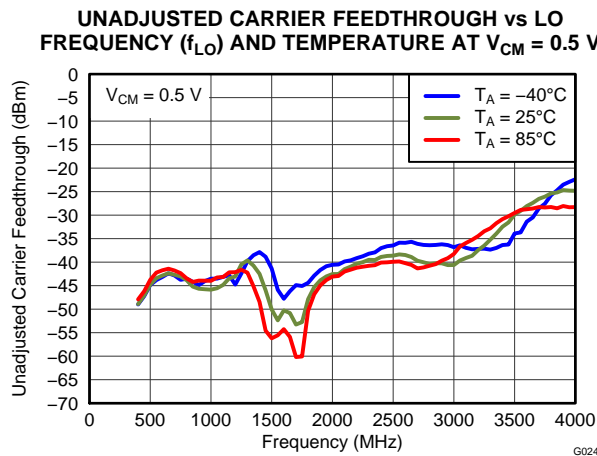


Figure 26.

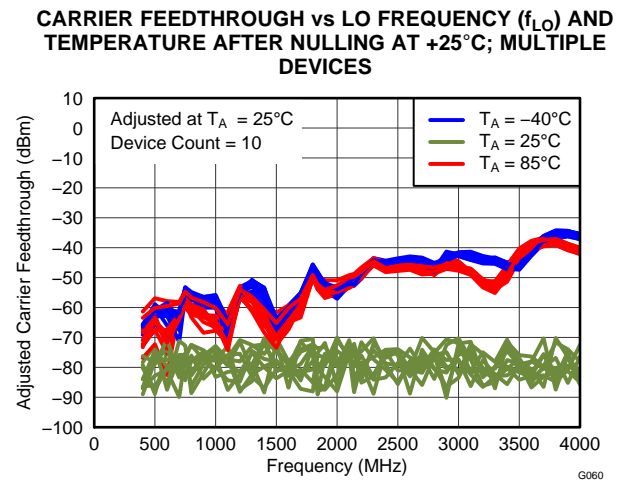


Figure 27.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

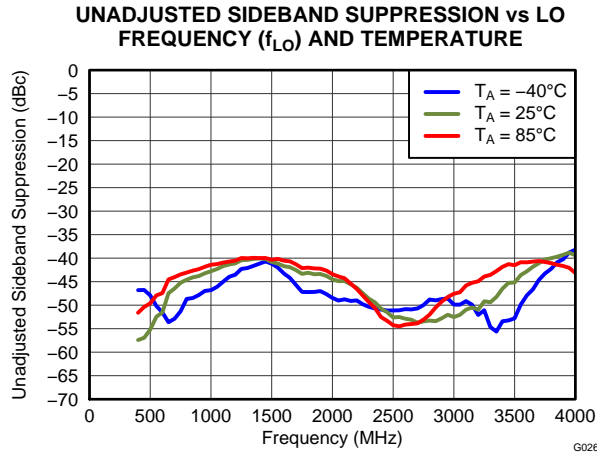


Figure 28.

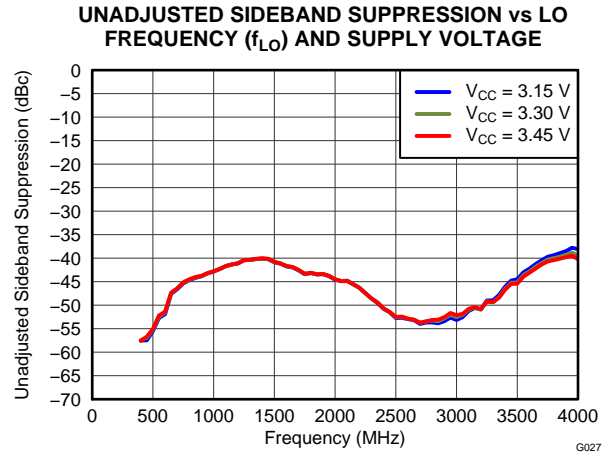


Figure 29.

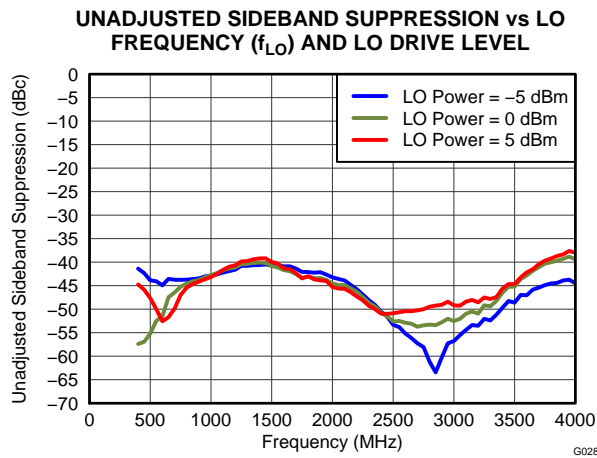


Figure 30.

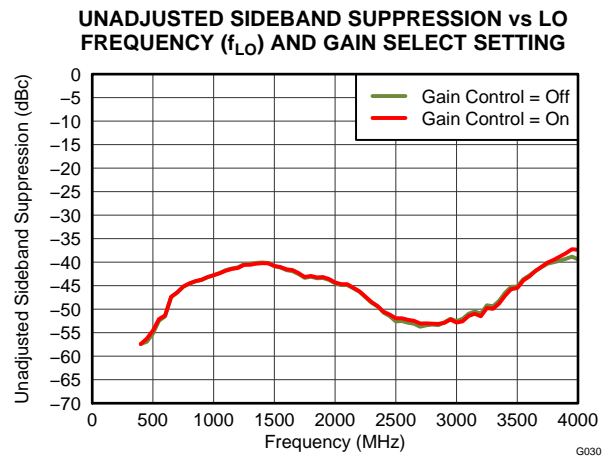


Figure 31.

**UNADJUSTED SIDEBAND SUPPRESSION vs LO FREQUENCY ( $f_{LO}$ ) AND TEMPERATURE AT  $V_{CM} = 0.5\text{ V}$**

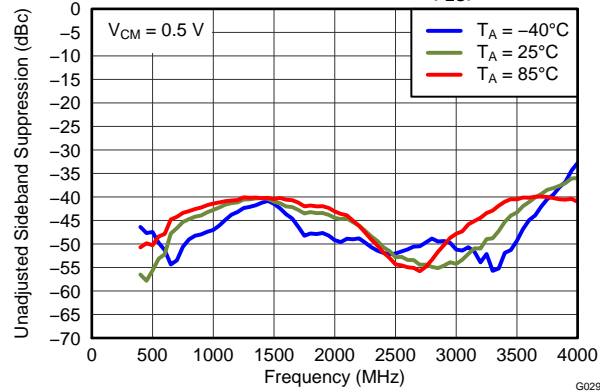


Figure 32.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband, Mid-Band Calibration**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted. Single point adjustment mid-band.

**ADJUSTED CARRIER FEEDTHROUGH vs LO FREQUENCY AND TEMPERATURE (750 LTE Band)**

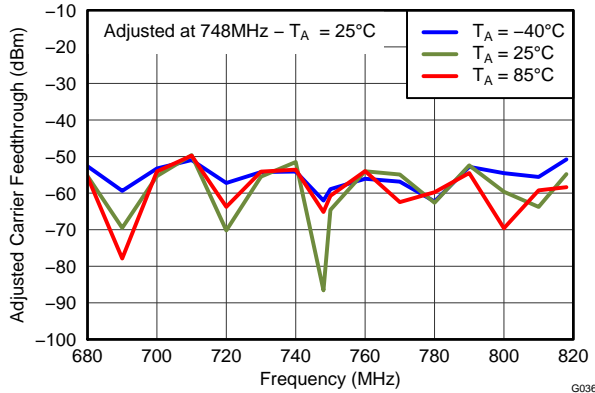


Figure 33.

**ADJUSTED CARRIER FEEDTHROUGH vs LO FREQUENCY AND TEMPERATURE (GSM900 Band)**

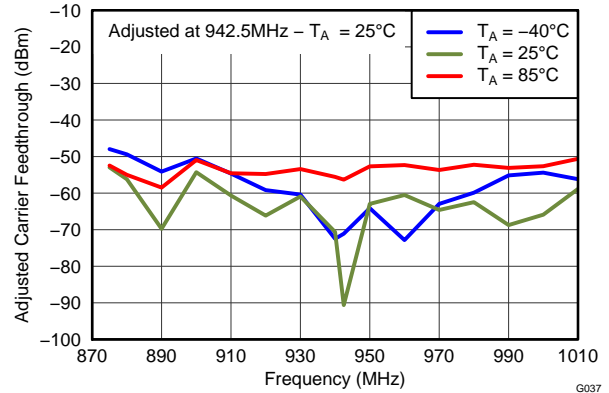


Figure 34.

**ADJUSTED CARRIER FEEDTHROUGH vs LO FREQUENCY AND TEMPERATURE (PCS Band)**

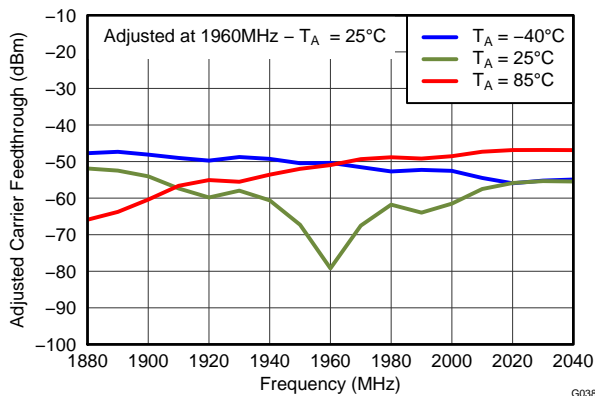


Figure 35.

**ADJUSTED CARRIER FEEDTHROUGH vs LO FREQUENCY AND TEMPERATURE (UMTS Band)**

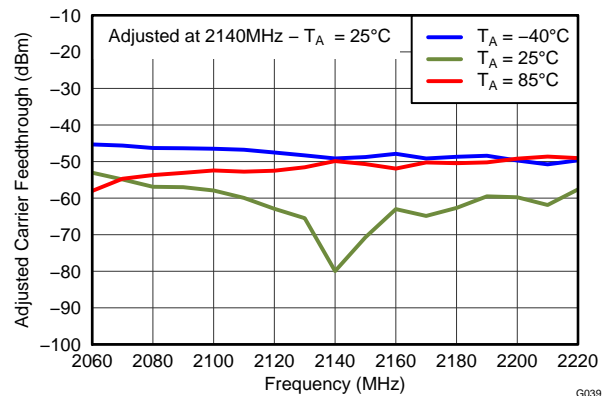


Figure 36.

**ADJUSTED CARRIER FEEDTHROUGH vs LO FREQUENCY AND TEMPERATURE (2.6 GHz LTE Band)**

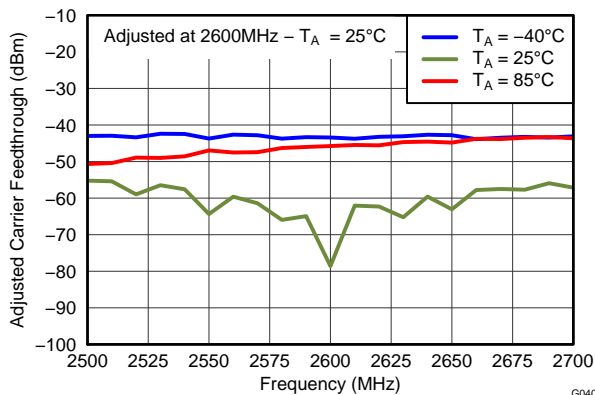


Figure 37.

**ADJUSTED CARRIER FEEDTHROUGH vs LO FREQUENCY AND TEMPERATURE (WiMAX/LTE Band)**

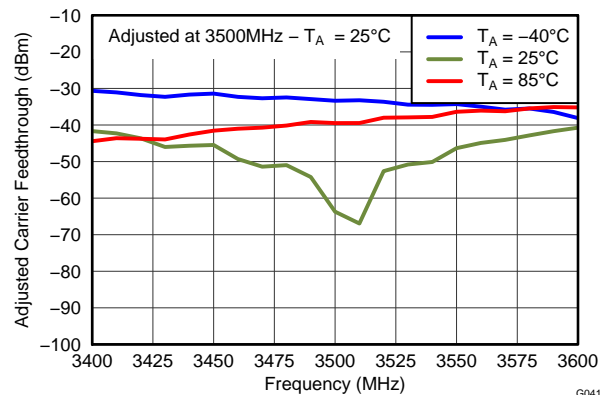


Figure 38.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband, Mid-Band Calibration (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted. Single point adjustment mid-band.

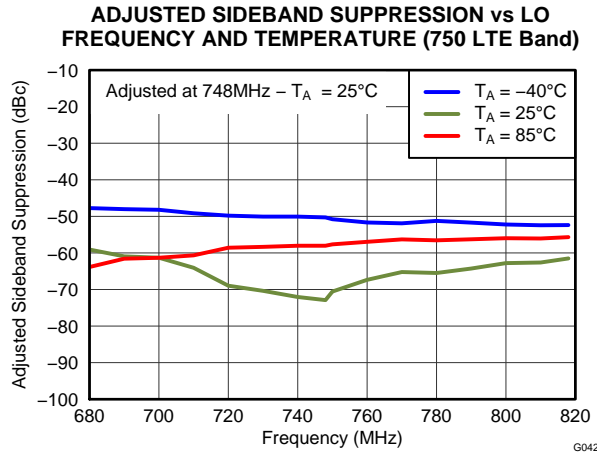


Figure 39.

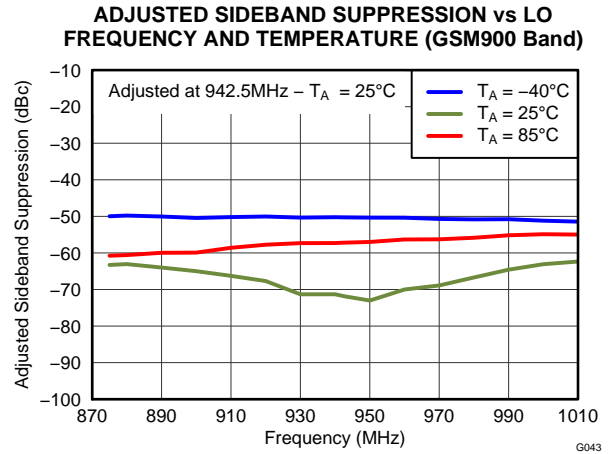


Figure 40.

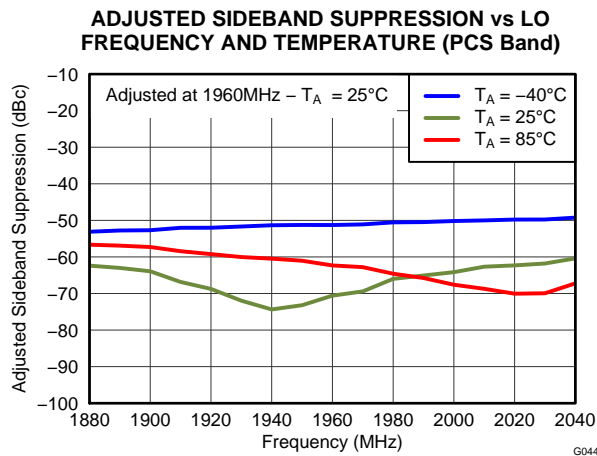


Figure 41.

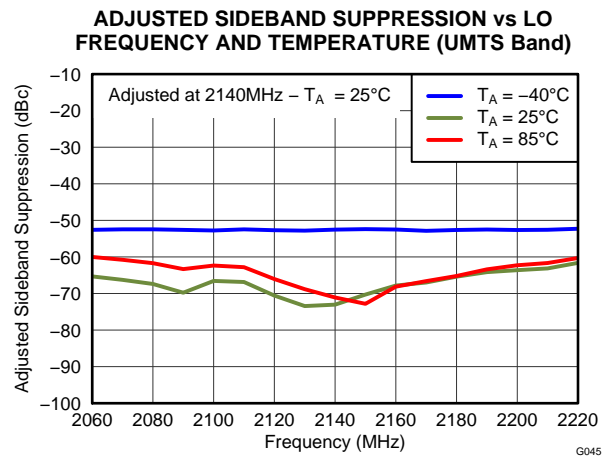


Figure 42.

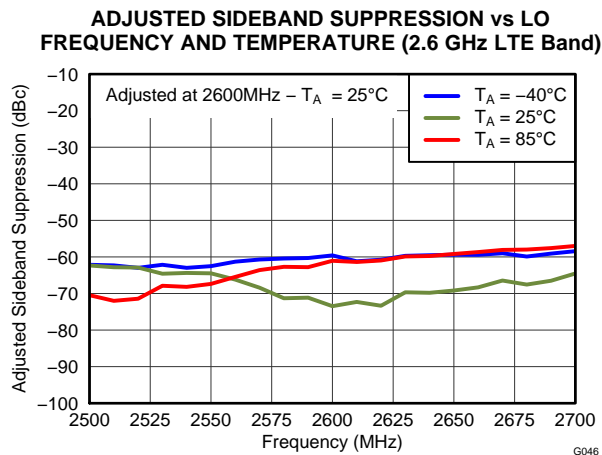


Figure 43.

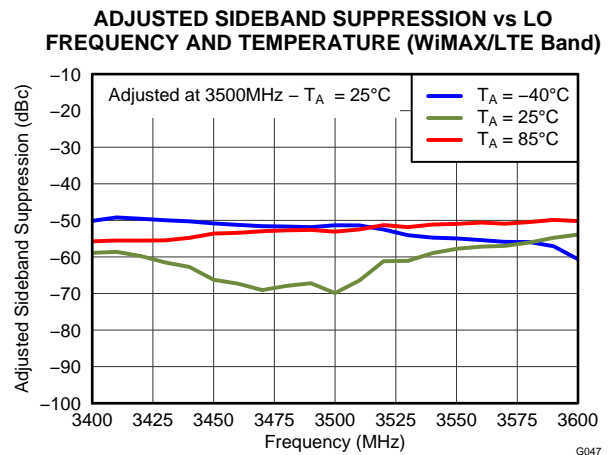


Figure 44.



**TYPICAL CHARACTERISTICS: No Baseband**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); and input baseband ports terminated in 50  $\Omega$ , unless otherwise noted.

**OUTPUT NOISE vs LO FREQUENCY ( $f_{LO}$ ) AND TEMPERATURE**

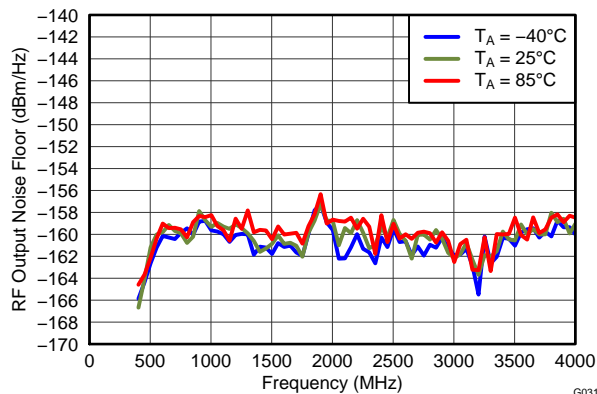


Figure 45.

**OUTPUT NOISE vs LO FREQUENCY ( $f_{LO}$ ) AND SUPPLY VOLTAGE**

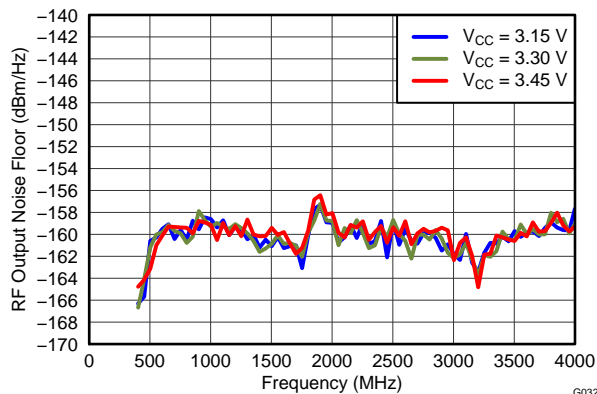


Figure 46.

**OUTPUT NOISE vs LO FREQUENCY ( $f_{LO}$ ) AND LO DRIVE LEVEL**

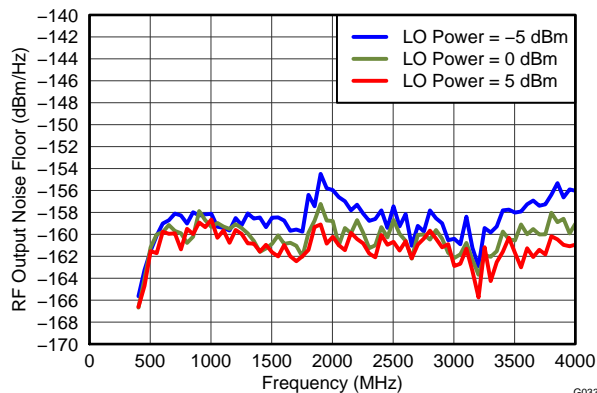


Figure 47.

**OUTPUT NOISE vs LO FREQUENCY ( $f_{LO}$ ) AND GAIN SELECT SETTING**

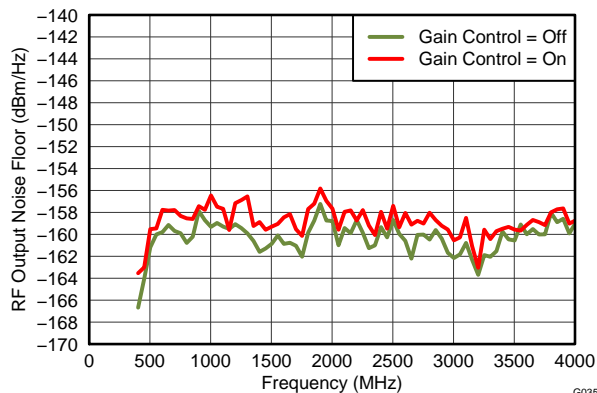


Figure 48.

**OUTPUT NOISE vs OUTPUT POWER**

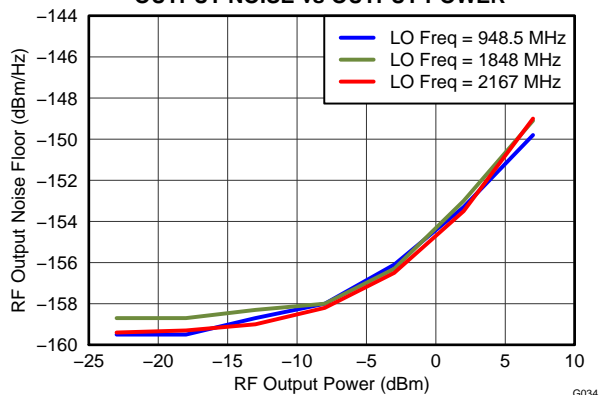


Figure 49.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ; LO = 0 dBm, single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

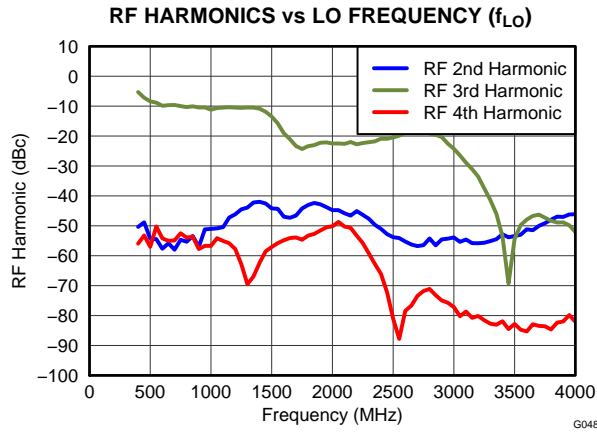


Figure 50.

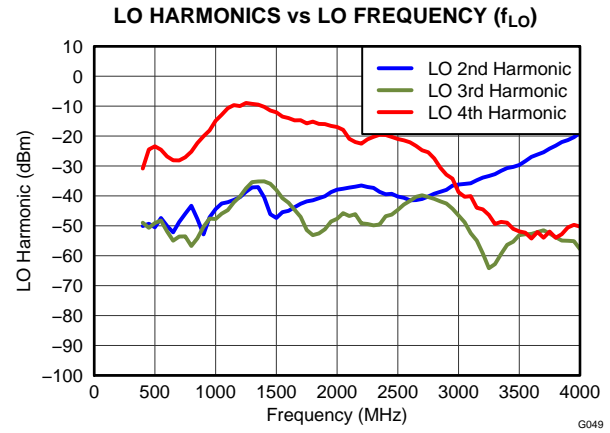


Figure 51.

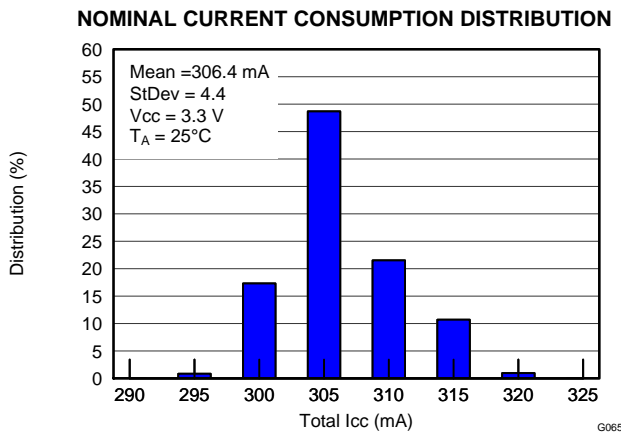


Figure 52.

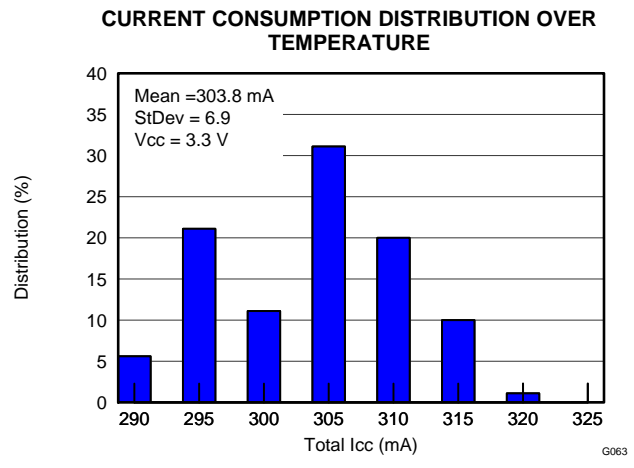


Figure 53.

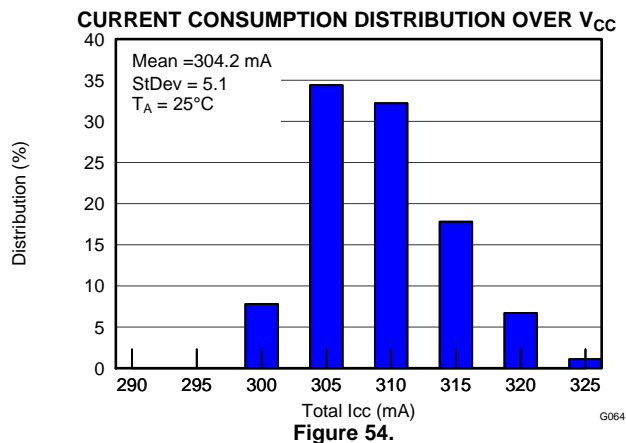


Figure 54.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ;  $LO = 0\text{ dBm}$ , single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

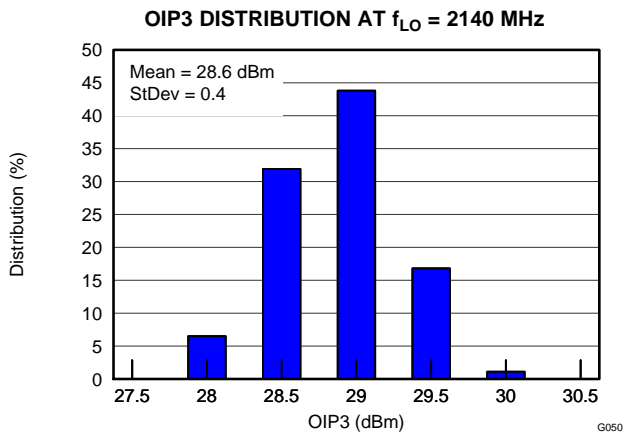


Figure 55.

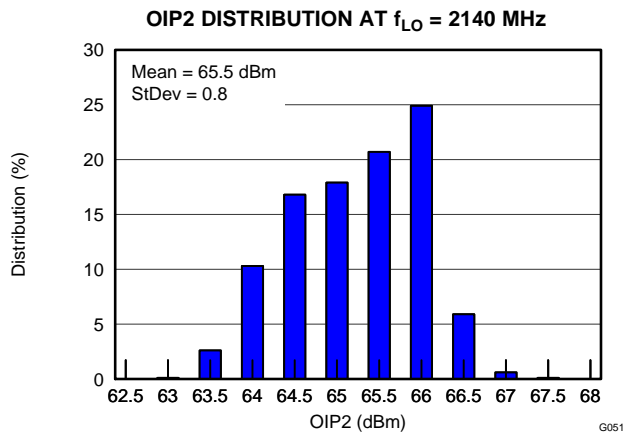


Figure 56.

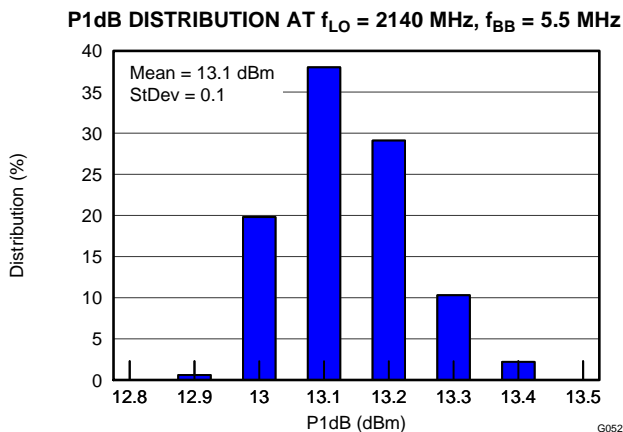


Figure 57.

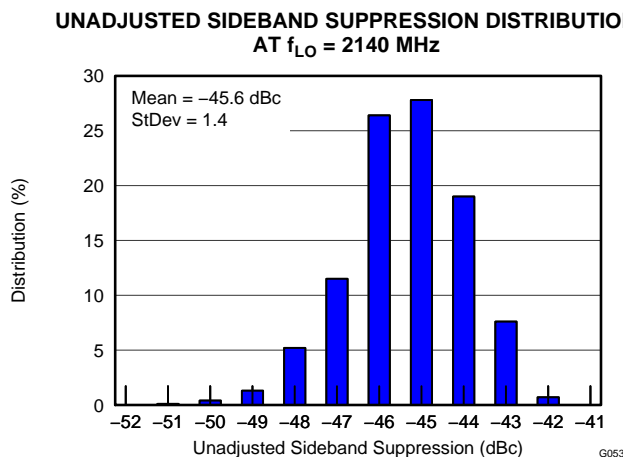


Figure 58.

**UNADJUSTED CARRIER FEEDTHROUGH DISTRIBUTION AT  $f_{LO} = 2140\text{ MHz}$**

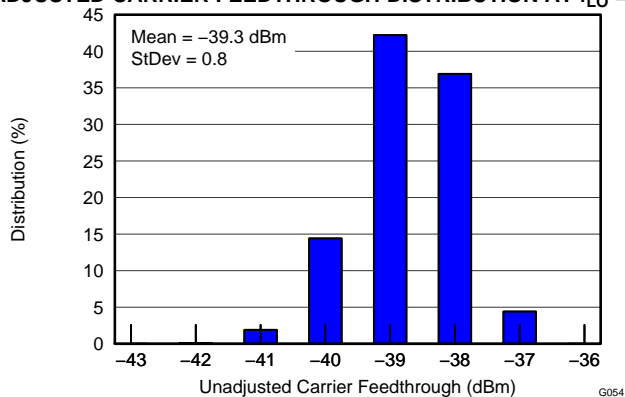


Figure 59.

**TYPICAL CHARACTERISTICS: Two-Tone Baseband (continued)**

$V_{CC} = 3.3\text{ V}$ ;  $T_A = +25^\circ\text{C}$ ;  $LO = 0\text{ dBm}$ , single-ended drive (LOP); I/Q frequency ( $f_{BB}$ ) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude =  $0.5 \cdot V_{PP}$ /tone differential sine waves in quadrature with  $V_{CM} = 0.25\text{ V}$ ; and broadband output match, unless otherwise noted.

**OIP3 DISTRIBUTION AT  $f_{LO} = 900\text{ MHz}$**

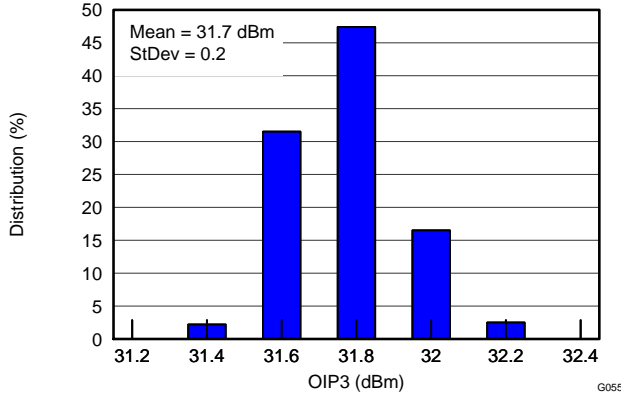


Figure 60.

**OIP2 DISTRIBUTION AT  $f_{LO} = 900\text{ MHz}$**

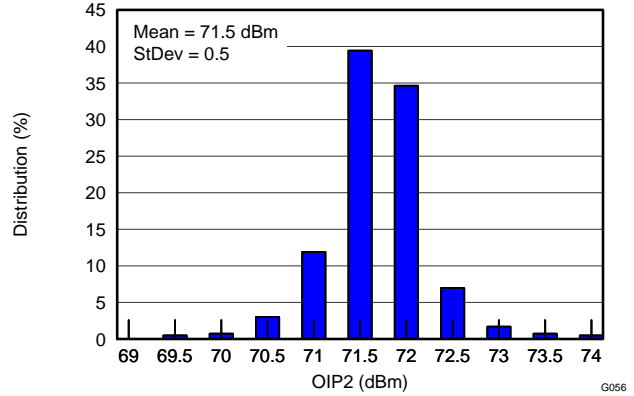


Figure 61.

**P1dB DISTRIBUTION AT  $f_{LO} = 900\text{ MHz}$ ,  $f_{BB} = 5.5\text{ MHz}$**

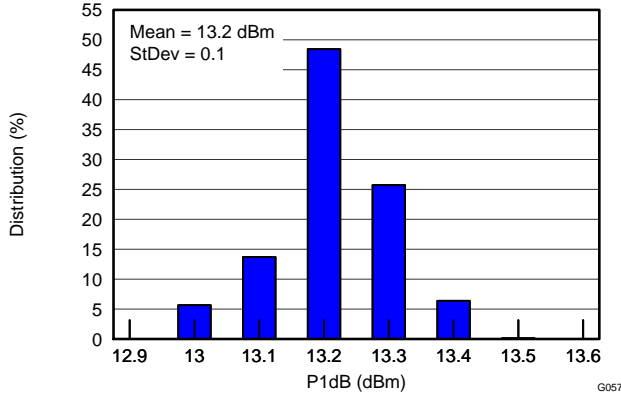


Figure 62.

**UNADJUSTED SIDEBAND SUPPRESSION DISTRIBUTION AT  $f_{LO} = 900\text{ MHz}$**

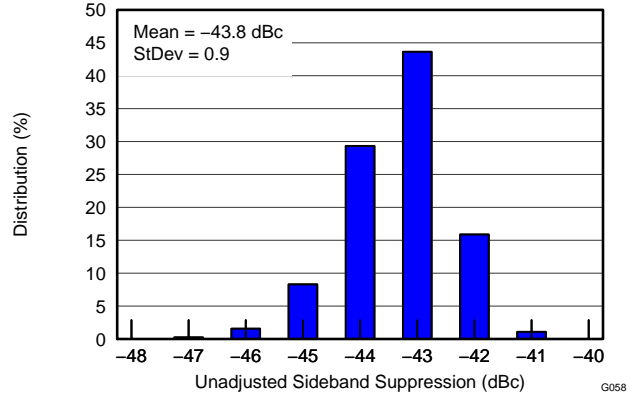


Figure 63.

**UNADJUSTED CARRIER FEEDTHROUGH DISTRIBUTION AT  $f_{LO} = 900\text{ MHz}$**

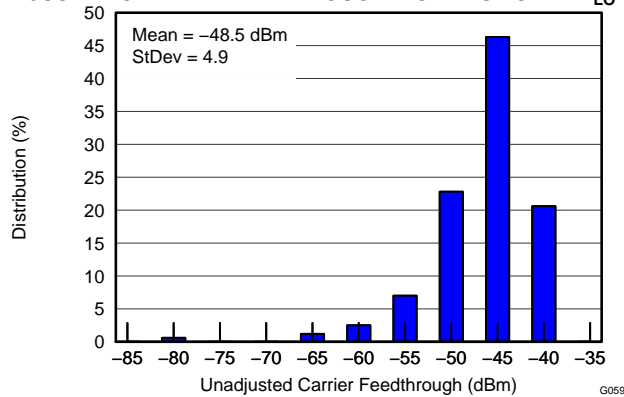


Figure 64.

## APPLICATION INFORMATION

### Application Schematic

Figure 65 shows a typical TRF3705 application schematic.

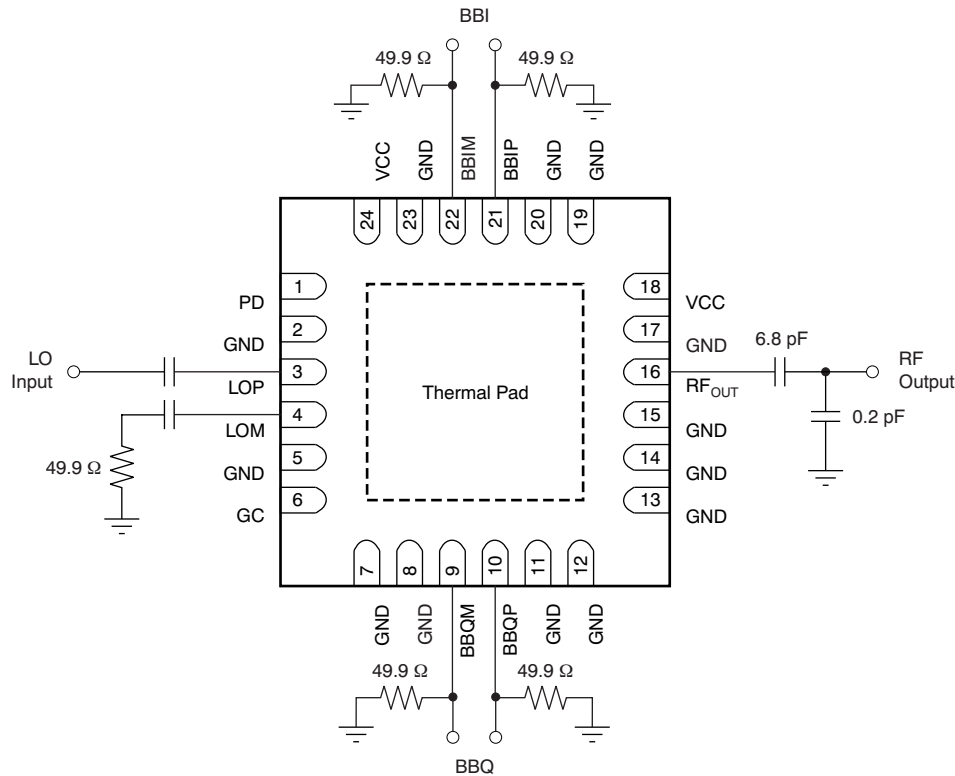


Figure 65. Typical Application Circuit

### Power Supply and Grounding

The TRF3705 is powered by supplying a nominal 3.3 V to pins 18 and 24. These supplies can be tied together and sourced from a single clean supply. Proper RF bypassing should be placed close to each power supply pin.

Ground pin connections should have at least one ground via close to each ground pin to minimize ground inductance. The PowerPAD™ must be tied to ground, preferably with the recommended ground via pattern to provide a good thermal conduction path to the alternate side of the board and to provide a good RF ground for the device. (Refer to [PCB Design Guidelines](#) for additional information.)

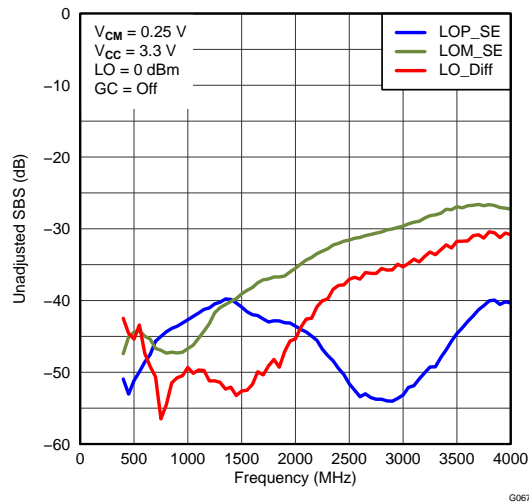
### Baseband Inputs

The baseband inputs consist of the in-phase signal (I) and the Quadrature-phase signal (Q). The I and Q lines are differential lines that are driven in quadrature. The nominal drive level is  $1-V_{PP}$  differential on each branch.

The baseband lines are nominally biased at  $0.25-V_{CM}$  common-mode voltage ( $V_{CM}$ ); however, the device can operate with a  $V_{CM}$  in the range of 0 V to 0.5 V. The baseband input lines are normally terminated in  $50 \Omega$ , though it is possible to modify this value if necessary to match to an external filter load impedance requirement.

## LO Input

The LO inputs can be driven either single-ended or differentially. There is no significant performance difference between either option with the exception of the sideband suppression. If driven single-ended, either input can be used, but LOP (pin 3) is recommended for best broadband performance of sideband suppression. When driving in single-ended configuration, simply ac-couple the unused port and terminate in 50  $\Omega$ . The comparison of the sideband suppression performance is shown in Figure 66 for driving the LO single-ended from either pin and for driving the LO input differentially.

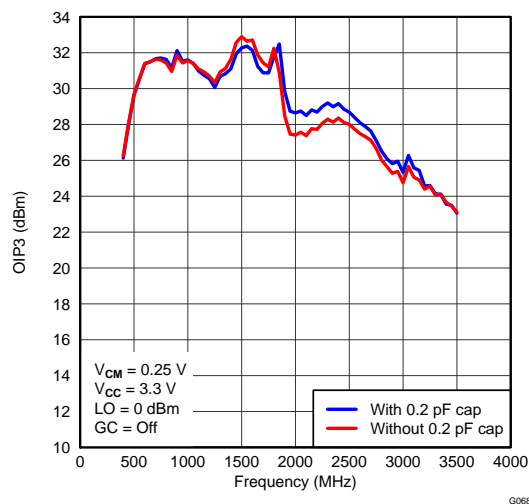


**Figure 66. Unadjusted Sideband Suppression (SBS) vs LO Drive Options**

## RF Output

The RF output must be ac-coupled and can drive a 50- $\Omega$  load. The suggested output match provides the best broadband performance across the frequency range of the device. It is possible to modify the output match to optimize performance within a selected band if needed. The optimized matching circuits are to match the RF output impedances to 50  $\Omega$ .

Figure 67 shows a slightly better OIP3 performance at the frequency above 1850 MHz with an 0.2-pF matching capacitor.



**Figure 67. OIP3 with and without a Shunt 0.2-pF Matching Capacitor at the RF Port**

### 350-MHz Operation

A different matching circuit, as shown in Figure 68, could also be applied to improve the performance for the frequency from 300 MHz to 400 MHz.

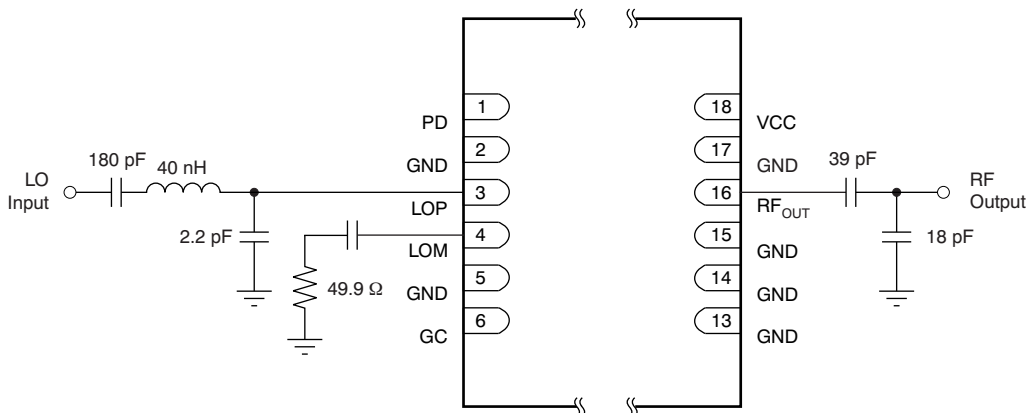


Figure 68. Matching Components for Operation Centered at 350 MHz

Figure 69 and Figure 70 show a slight improvement in OIP3 performance at frequencies above 1850 MHz with an 0.2-pF matching capacitor.

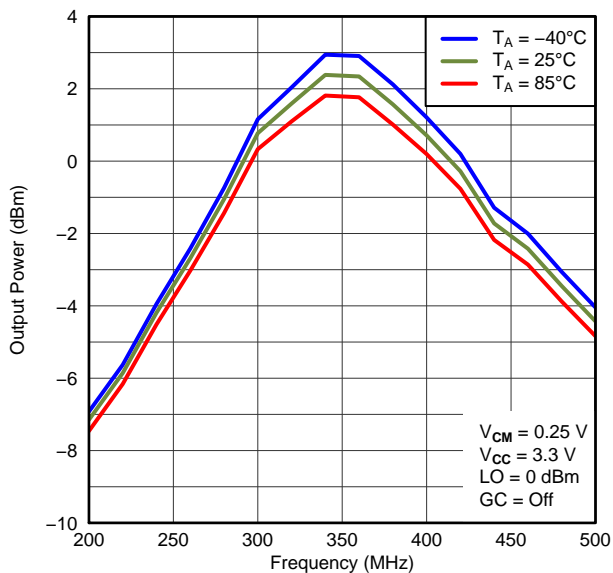


Figure 69. Output Power with 350-MHz Matching Circuit

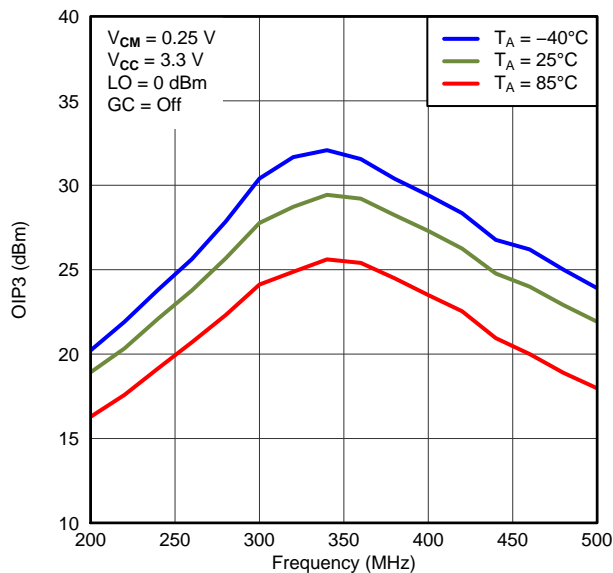
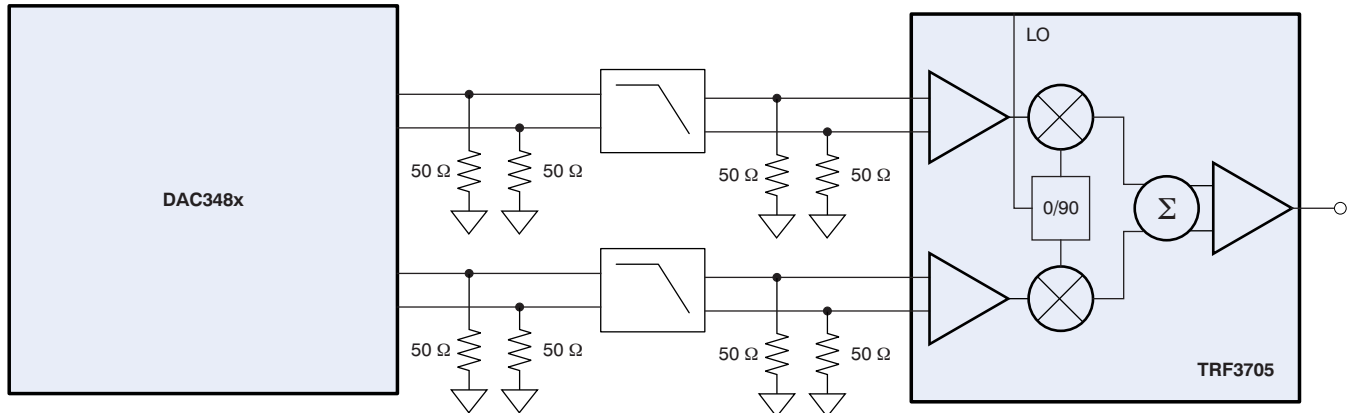


Figure 70. OIP3 with 350-MHz Matching Circuit

## DAC to Modulator Interface Network

For optimum linearity and dynamic range, a digital-to-analog converter (DAC) can interface directly with the TRF3705 modulator. It is imperative that the common-mode voltage of the DAC and the modulator baseband inputs be properly maintained. With the proper interface network, the common-mode voltage of the DAC can be translated to the proper common-mode voltage of the modulator. The TRF3705 common-mode voltage is typically 0.25 V, and is ideally suited to interface with the [DAC3482/3484](#) (DAC348x) family because the common-mode voltages of both devices are the same; there is no translation network required. The interface network is shown in [Figure 71](#).



**Figure 71. DAC348x Interface with the TRF3705 Modulator**

The DAC348x requires a load resistor of 25  $\Omega$  per branch to maintain its optimum voltage swing of  $1-V_{PP}$  differential with a 20-mA max current setting. The load of the DAC is separated into two parallel 50- $\Omega$  resistors placed on the input and output side of the low-pass filter. This configuration provides the proper resistive load to the DAC while also providing a convenient 50- $\Omega$  source and load termination for the filter.

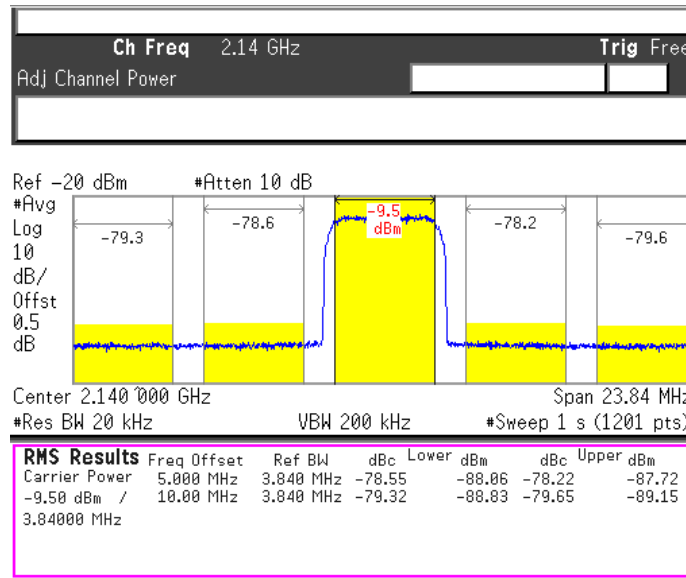
## DAC348x with TRF3705 Modulator Performance

The combination of the DAC348x driving the TRF3705 modulator yields excellent system parameters suitable for high-performance applications. As an example, the following sections illustrate the typical modulated adjacent channel power ratio (ACPR) for common telecom standards and bands. These measurements were taken on the [DAC348x evaluation board](#).



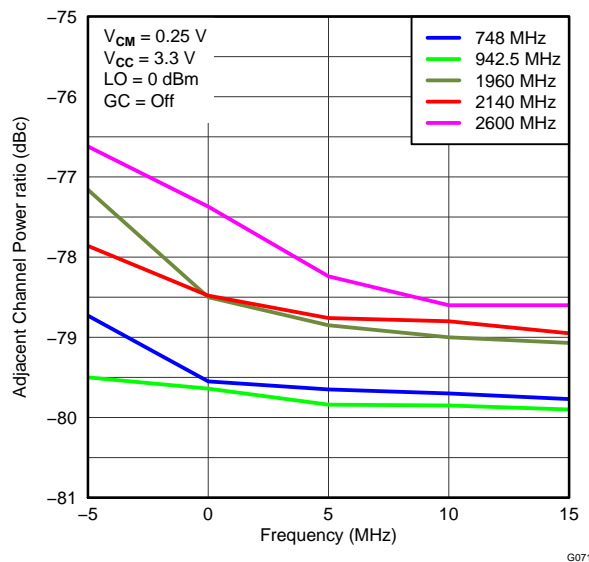
**WCDMA**

The adjacent channel power ratio (ACPR) performance using a single-carrier WCDMA signal in the UMTS band is shown in [Figure 72](#).



**Figure 72. Single-Carrier WCDMA ACPR, IF = 30 MHz, LO Frequency = 2110 MHz**

A marginal improvement in OIP3 and output noise performance can be observed by increasing the LO drive power, resulting in slightly improved ACPR performance. The ACPR performance versus LO drive level is plotted in [Figure 73](#) across common frequencies to illustrate the amount of improvement that is possible.



**Figure 73. Single-Carrier WCDMA ACPR Performance vs LO Power**

**LTE**

ACPR performance using a 10 MHz LTE signal in the 700-MHz band is shown in Figure 74.

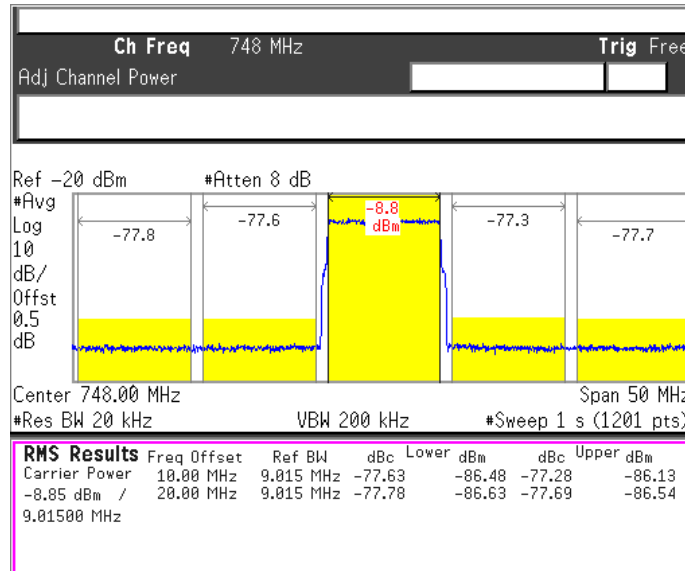


Figure 74. 10 MHz LTE ACPR, IF = 30 MHz, LO Frequency = 718 MHz

**MC-GSM**

ACPR performance using a four-carrier MC-GSM signal in the 1800-MHz band is shown in Figure 75.

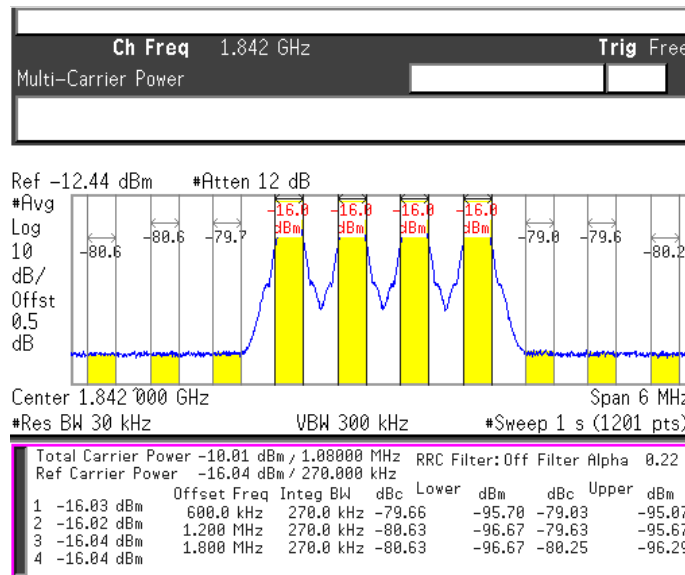


Figure 75. Four-Carrier MC-GSM, IF = 30 MHz ACPR, LO Frequency = 1812 MHz

## DEFINITION OF SPECIFICATIONS

### Carrier Feedthrough

This specification measures the power of the local oscillator component that is present at the output spectrum of the modulator. The performance depends on the dc offset balance within the baseband input lines. Ideally, if all of the baseband lines were perfectly matched, the carrier (that is, the LO) would be naturally suppressed; however, small dc offset imbalances within the device allow some of the LO component to feed through to the output. This parameter is expressed as an absolute power in dBm, and is independent of the RF output power and the injected LO input power.

It is possible to adjust the baseband dc offset balance to suppress the output carrier component. Devices such as the DAC348x DAC family have dc offset adjustment capabilities specifically for this function. The Adjusted Carrier Feedthrough graphs (see [Figure 33](#) through [Figure 38](#)) optimize the performance at the center of the band at room temperature. Then, with the adjusted dc offset values held constant, the parameter is measured over the frequency band and across the temperature extremes. The typical performance plots provide an indication of how well the adjusted carrier suppression can be maintained over frequency and temperature with only one calibration point.

### Sideband Suppression

This specification measures the suppression of the undesired sideband at the output of the modulator relative to the desired sideband. If the amplitude and phase within the I and Q branch of the modulator were perfectly matched, the undesired sideband (or image) would be naturally suppressed. Amplitude and phase imbalance in the I and Q branches result in the increase of the undesired sideband. This parameter is measured in dBc relative to the desired sideband.

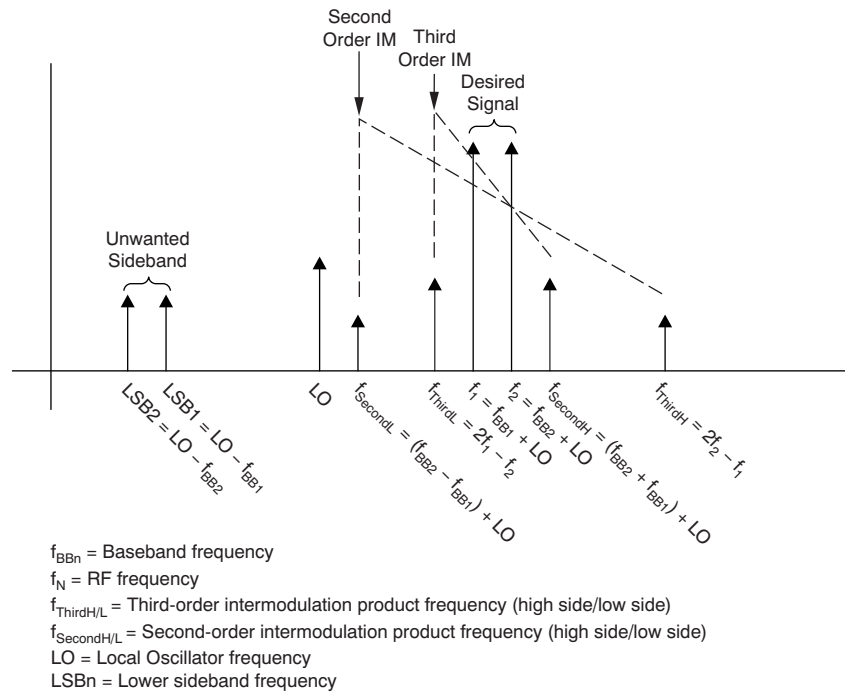
It is possible to adjust the relative amplitude and phase balance within the baseband lines to suppress the unwanted sideband. Devices such as the DAC348x DAC family have amplitude and phase adjustment control specifically for this function. The Adjusted Sideband Suppression graphs (refer to [Figure 39](#) through [Figure 44](#)) optimize the performance at the center of the band at room temperature. Then, with the adjusted amplitude and phase values held constant, the parameter is measured over the frequency band and across the temperature extremes. The performance plots provide an indication of how well the adjusted sideband suppression can be maintained over frequency and temperature with only one calibration point.

### Output Noise

The output noise specifies the absolute noise power density that is output from the RF<sub>OUT</sub> pin (pin 16). This parameter is expressed in dBm/Hz. This parameter, in conjunction with the OIP3 specification, indicates the dynamic range of the device. In general, at high output signal levels the performance is limited by the linearity of the device; at low output levels, on the other hand, the performance is limited by noise. As a result of the higher gain and output power of the TRF3705 compared to earlier devices, it is expected that the noise density is slightly higher as well. With its increased gain and high OIP3 performance, the overall dynamic range of the TRF3705 is maintained at exceptional levels.

## Definition of Terms

A simulated output spectrum with two tones is shown in [Figure 76](#), with definitions of various terms used in this data sheet.



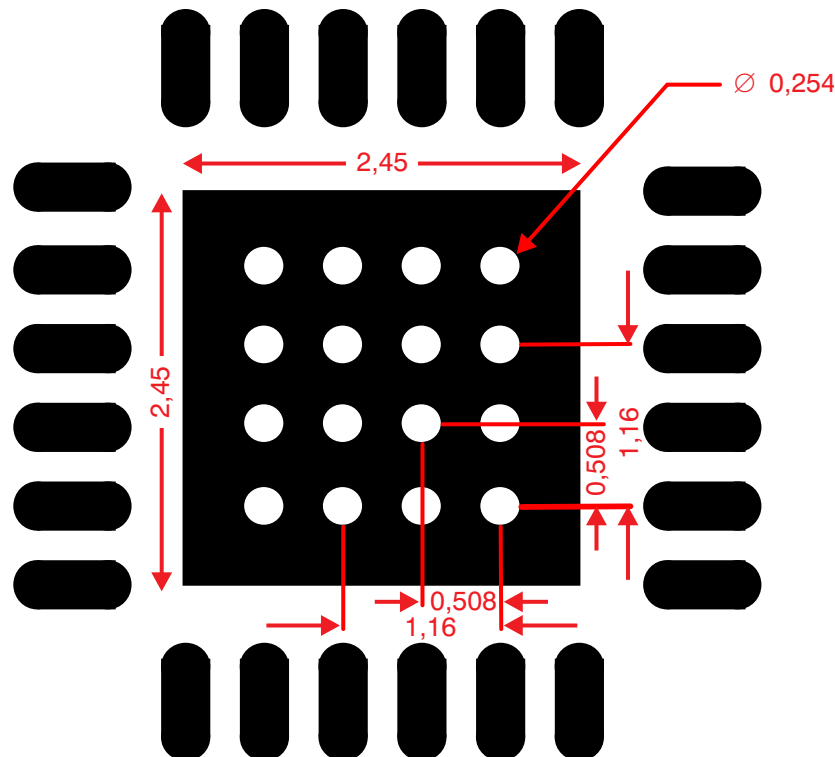
**Figure 76. Graphical Illustration of Common Terms**

## EVALUATION BOARD

Populated RoHS-compliant evaluation boards are available for testing the TRF3705 as a stand-alone device. Contact your local TI representative for information on ordering these evaluation modules, or see the [TRF3705 product folder](#) on the TI website. In addition, the TRF3705 can be evaluated with the DAC348x (quad/dual 16-bit, 1.25GSPS) EVM driving the baseband inputs through a seamless interface at 0.25V common-mode voltage.

### PCB Design Guidelines

The TRF3705 device is fitted with a ground slug on the back of the package that must be soldered to the printed circuit board (PCB) ground with adequate ground vias to ensure a good thermal and electrical connection. The recommended via pattern and ground pad dimensions are shown in [Figure 77](#). The recommended via diameter is 10 mils (0.10 in or 0,25 mm). The ground pins of the device can be directly tied to the ground slug pad for a low-inductance path to ground. Additional ground vias may be added if space allows.



Note: Dimensions are in millimeters (mm).

**Figure 77. PCB Ground Via Layout Guide**

Decoupling capacitors at each of the supply pins are strongly recommended. The value of these capacitors should be chosen to provide a low-impedance RF path to ground at the frequency of operation. Typically, the value of these capacitors is approximately 10 pF or lower.

The device exhibits symmetry with respect to the quadrature input paths. It is recommended that the PCB layout maintain this symmetry in order to ensure that the quadrature balance of the device is not impaired. The I/Q input traces should be routed as differential pairs and the respective lengths all kept equal to each other. On the RF traces, maintain proper trace widths to keep the characteristic impedance of the RF traces at a nominal 50 Ω.

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Should this evaluation board/kit not meet the specifications indicated in the User's Guide, the board/kit may be returned within 30 days from the date of delivery for a full refund. **THE FOREGOING WARRANTY IS THE EXCLUSIVE WARRANTY MADE BY SELLER TO BUYER AND IS IN LIEU OF ALL OTHER WARRANTIES, EXPRESSED, IMPLIED, OR STATUTORY, INCLUDING ANY WARRANTY OF MERCHANTABILITY OR FITNESS FOR ANY PARTICULAR PURPOSE.**

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## EVM Warnings and Restrictions

It is important to operate this EVM within the input voltage range of 0 V to 3.6 V and the output voltage range of 0 V to 3.6 V.

Exceeding the specified input range may cause unexpected operation and/or irreversible damage to the EVM. If there are questions concerning the input range, please contact a TI field representative prior to connecting the input power.

Applying loads outside of the specified output range may result in unintended operation and/or possible permanent damage to the EVM. Please consult the EVM User's Guide prior to connecting any load to the EVM output. If there is uncertainty as to the load specification, please contact a TI field representative.

During normal operation, some circuit components may have case temperatures greater than 55° C. The EVM is designed to operate properly with certain components above 55° C as long as the input and output ranges are maintained. These components include but are not limited to linear regulators, switching transistors, pass transistors, and current sense resistors. These types of devices can be identified using the EVM schematic located in the EVM User's Guide. When placing measurement probes near these devices during operation, please be aware that these devices may be very warm to the touch.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
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**PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup>    | Lead/<br>Ball Finish | MSL Peak Temp <sup>(3)</sup> | Samples<br>(Requires Login) |
|------------------|-----------------------|--------------|-----------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| TRF3705IRGER     | ACTIVE                | VQFN         | RGE             | 24   | 3000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG          | Level-2-260C-1 YEAR          |                             |
| TRF3705IRGET     | ACTIVE                | VQFN         | RGE             | 24   | 250         | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG          | Level-2-260C-1 YEAR          |                             |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

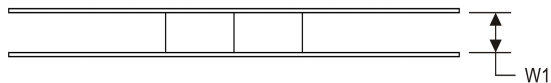
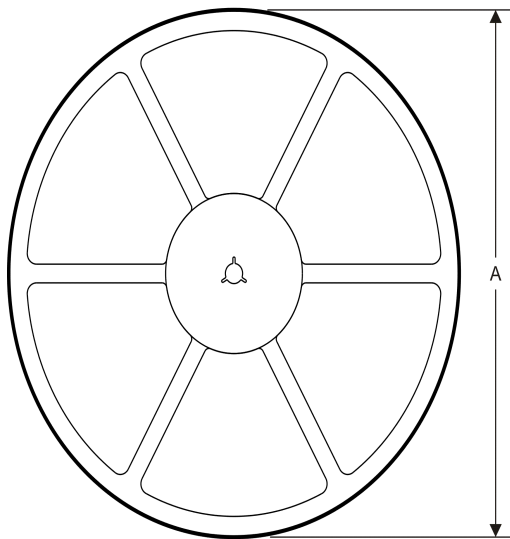
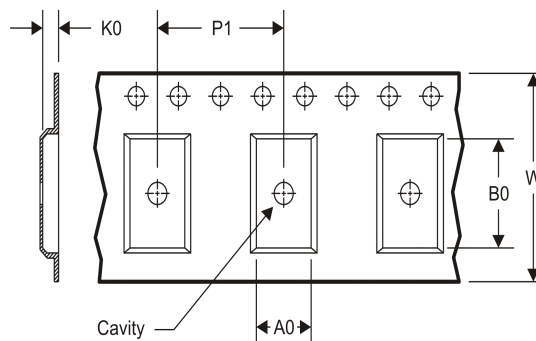
**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


|    |   |
|----|---|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

**TAPE AND REEL INFORMATION**

\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TRF3705IRGER | VQFN         | RGE             | 24   | 3000 | 330.0              | 12.4               | 4.3     | 4.3     | 1.5     | 8.0     | 12.0   | Q2            |
| TRF3705IRGET | VQFN         | RGE             | 24   | 250  | 330.0              | 12.4               | 4.3     | 4.3     | 1.5     | 8.0     | 12.0   | Q2            |



**TAPE AND REEL BOX DIMENSIONS**

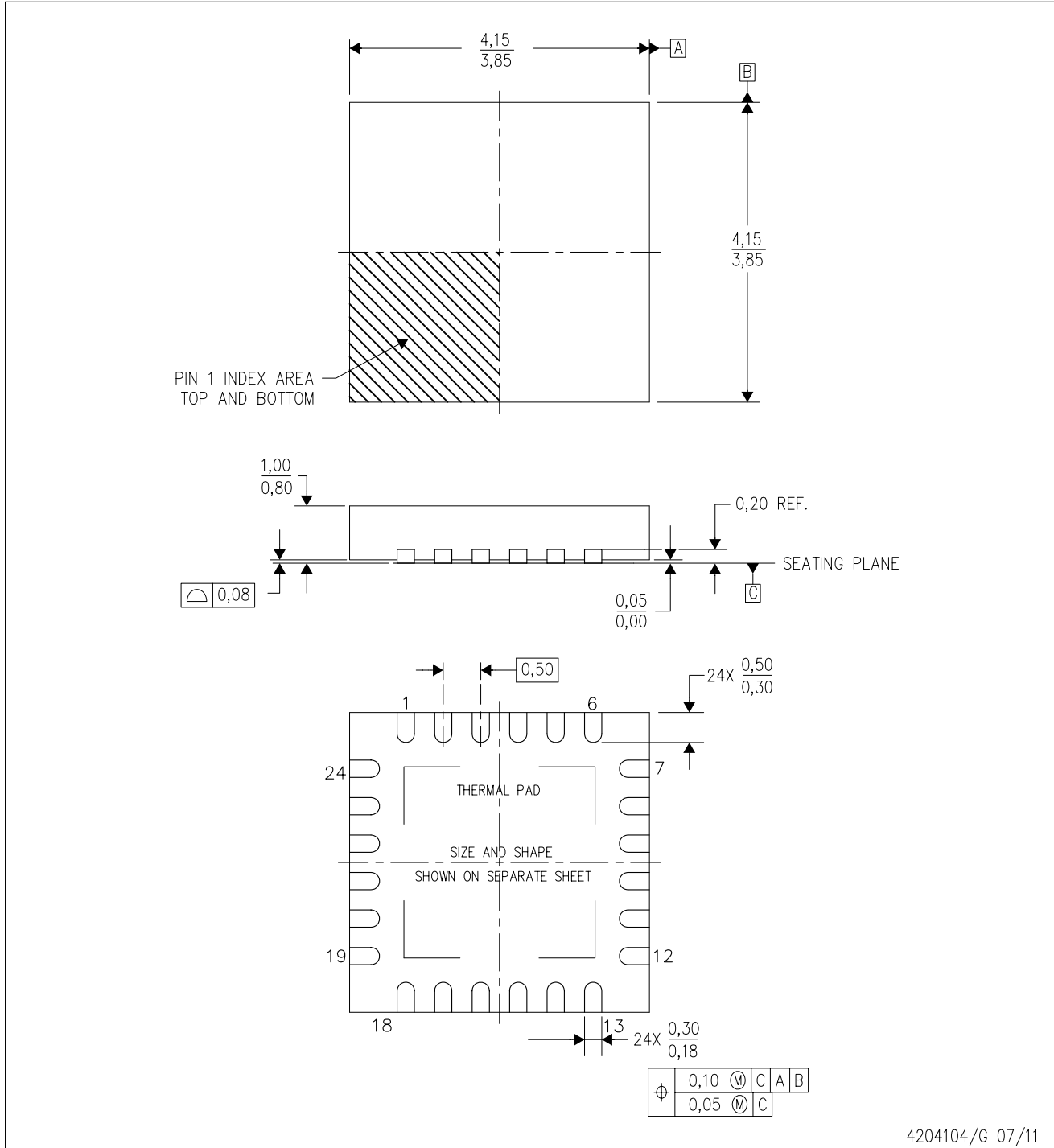

\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TRF3705IRGER | VQFN         | RGE             | 24   | 3000 | 338.1       | 338.1      | 20.6        |
| TRF3705IRGET | VQFN         | RGE             | 24   | 250  | 338.1       | 338.1      | 20.6        |

# MECHANICAL DATA

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - Quad Flatpack, No-Leads (QFN) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - Falls within JEDEC MO-220.

# THERMAL PAD MECHANICAL DATA

RGE (S-PVQFN-N24)

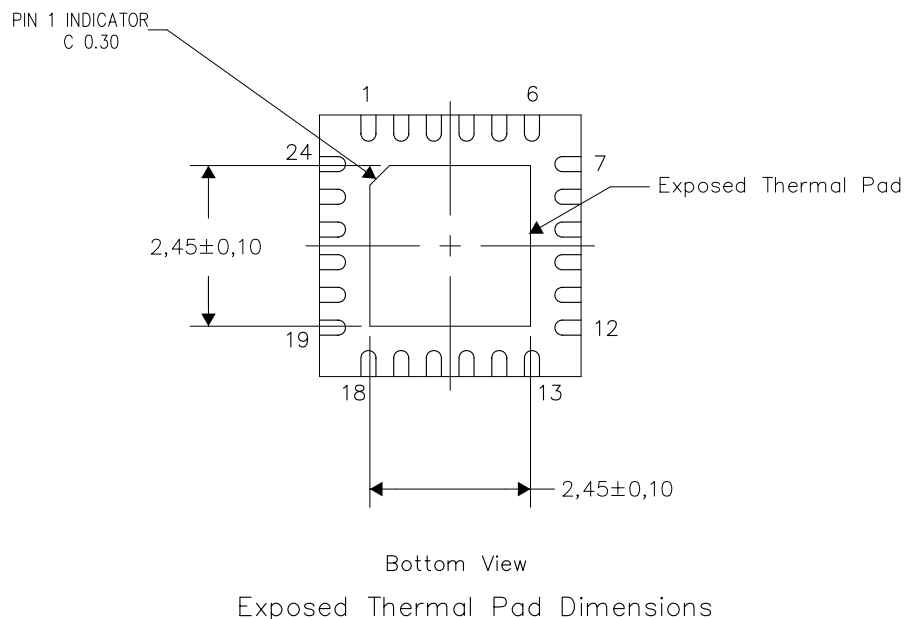
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.

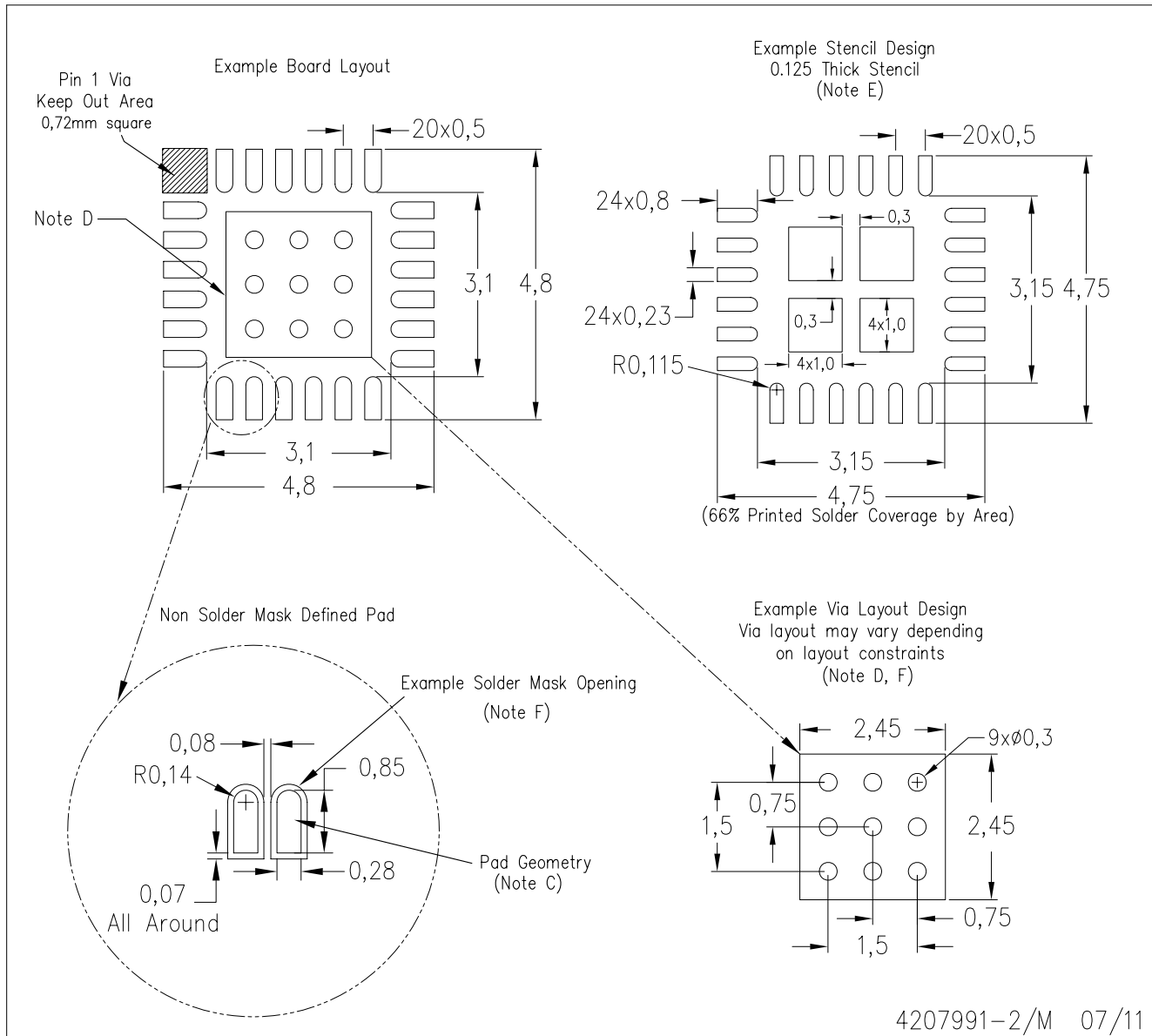


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NOTES: A. All linear dimensions are in millimeters

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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